

DEVSIM Manual

Release Beta 0.01

Devsim LLC

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Chapter 1

Front Matter

1.1 Contact

Web:	https://www.devsim.com
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Open Source Project:	https://www.devsim.org

1.2 Copyright

Copyright © 2009-2017 DEVSIM LLC

This work is licensed under a Creative Commons Attribution-NoDerivs 3.0 Unported License. http://creativecommons.org/licenses/by-nd/3.0/deed.en_US

1.3 Disclaimer

DEVSIM LLC MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARD TO THIS MATERIAL, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE.

1.4 Trademark

DEVSIM is a registered trademark and SYMDIFF is a trademark of DEVSIM LLC. All other product or company names are trademarks of their respective owners.

Chapter 2

Release Notes

2.1 Introduction

DEVSIM download and installation instructions are located in *Installation* (page 51). The following sections list bug fixes and enhancements over time. The official website for this project is located at https://www.devsim.org.

2.2 Updates Since The Last Release

2.2.1 Platforms

- The Ubuntu 16.04 (LTS) platform is now supported.
- The Ubuntu 12.04 (LTS), Centos 5 (Red Hat 5 compatible) platforms are no longer supported. These platforms are no longer supported by their vendors.
- Apple Mac OS X compiled with flat_namespace to allow substitution of dynamically linked libraries.

_ Microsoft Windows 7 is compiled using Microsoft Visual Studio 2017.

2.2.2 Binary Releases

- Releases available from https://github.com/devsim/devsim/releases.
- Centos 6 released is linked against the Intel Math Kernel Library.
- Microsoft Windows 7 release is linked against the Intel Math Kernel Library
- Apple Mac OS X can optionally use the Intel Math Kernel Library.
- Anaconda Python 2.7 is the recommended distribution.
- Please see release notes for more information.

2.2.3 Bug Fixes

- 3d element edge derivatives were not being evaluated correctly
- 3d equation model evaluation for element edge models

2.2.4 Enhancements

- Build scripts are provided to build on various platforms.
- DEVSIM mesh format stores elements, instead of just nodes, for contact and interfaces
- The ds.create_gmsh_mesh() (page 74) command can be used to create a device from a provided list of elements.

2.2.5 Example Availability

- Density gradient simulation of MOSCAP example available from https://github.com/devsim/devsim_density_gradient.
- BJT simulation example available from https://github.com/devsim/devsim_bjt_example.

2.3 February 6, 2016

DEVSIM is now covered by the Apache License, Version 2.0 [ApacheSoftwareFoundation] (page 111). Please see the NOTICE and LICENSE file for more information.

2.4 November 24, 2015

2.4.1 Python Help

The Python interpreter now has documentation for each command, derived from the documentation in the manual. For example, help for the ds.solve() (page 90) can be found using:

help("ds.solve")

2.4.2 Manual Updates

The manual has been updated so that commands are easier to find in the index. Every command now has a short description. Cross references have been fixed. The date has been added to the front page.

2.5 November 1, 2015

2.5.1 Convergence Info

The ds.solve() (page 90) now supports the info option. The solve command will then return convergence information.

2.5.2 Python Interpreter Changes

The way DEVSIM commands are loaded into the ds module has been changed. It is now possible to see the full list of DEVSIM commands by typing

```
help('ds')
```

in the Python interpreter.

2.5.3 Platform Improvements and Binary Availability

Many improvements have been made in the way binaries are generated for the Linux, Apple Mac OS X, and Microsoft Windows platforms.

For Linux (see linux.txt):

- Create Centos 5, (Red Hat Enterprise Linux 5 compatible) build
- Build uses Intel Math Kernel Library math libraries (community edition)
- Build uses any compatible Python 2.7, including Anaconda
- Build compatible with newer Linux distributions.

For Apple Mac OS X (see macos.txt):

- Uses the system Python 2.7 on Mac OS X 10.10 (Yosemite)
- Provide instructions to use Anaconda Python

For Microsoft Windows (see windows.txt):

- Uses any compatible Python 2.7, including Anaconda
- Build uses Intel Math Kernel Library Community Edition

Binary releases are available for these platforms at https://www.devsim.org.

2.6 September 6, 2015

The ds.set_node_values() (page 88) takes a new option, values. It is a list containing values to set for all of the nodes in a region.

The following new commands have been added:

```
• ds.get_equation_list() (page 63)
```

- ds.get_contact_equation_list() (page 62)
- ds.get_interface_equation_list() (page 63)
- ds.delete_equation() (page 60)
- ds.delete_contact_equation() (page 60)
- ds.delete_interface_equation() (page 61)
- ds.get_equation_command() (page 62)
- ds.get_contact_equation_command() (page 62)
- ds.get_interface_equation_command() (page 63)

2.7 August 10, 2015

The ds.create_contact_from_interface() (page 73) may be used to create a contact at the location of an interface. This is useful when contact boundary conditions are needed for a region connected to the interface.

2.8 July 16, 2015

The ds.set_node_value() (page 87) was not properly setting the value. This issue is now resolved.

2.9 June 7, 2015

The ds.equation() (page 61) now supports the edge_volume_model. This makes it possible to integrate edge quantities properly so that it is integrated with respect to the volume on nodes of the edge. To set the node volumes for integration, it is necessary to define a model for the node volumes on both nodes of the edge. For example:

```
ds.edge_model(device="device", region="region", name="EdgeNodeVolume",
    equation="0.5*EdgeCouple*EdgeLength")
set_parameter(name="edge_node0_volume_model", value="EdgeNodeVolume")
set_parameter(name="edge_node1_volume_model", value="EdgeNodeVolume")
```

For the cylindrical coordinate system in 2D, please see Cylindrical Coordinate Systems (page 27).

Mac OS X 10.10 (Yosemite) is now supported. Regression results in the source distribution are for a 2014 Macbook Pro i7 running this operating system.

2.10 October 4, 2014

2.10.1 Platform Availability

The software is now supported on the Microsoft Windows. Please see *Supported platforms* (page 51) for more information.

2.11 December 25, 2013

2.11.1 Binary Availability

Binary versions of the DEVSIM software are available for download from http://sourceforge.net/projects/devsim. Current versions available are for

- Mac OS X 10.10 (Yosemite)
- Red Hat Enterprise Linux 6
- Ubuntu 12.04 (LTS)

Please see *Installation* (page 51) for more information.

2.11.2 Platforms

Mac OS X 10.10 (Yosemite) is now supported. Support for 32 bit is no longer supported on this platform, since the operating system is only released as 64 bit.

Regression data will no longer be maintained in the source code repository for 32 bit versions of Ubuntu 12.04 (LTS) and Red Hat Enterprise Linux 6. Building and running on these platforms will still be supported.

2.11.3 Source code improvements

The source code has been improved to compile on Mac $\,$ OS $\,$ X $\,$ 10.10 (Yosemite) and to comply with C++11 language standards. Some of the structure of the project has been reorganized. These changes to the infrastructure will help to keep the program maintainable and useable into the future.

2.12 September 8, 2013

2.12.1 Convergence

If the simulation is diverging for 5 or more iterations, the simulation stops.

2.12.2 Bernoulli Function Derivative Evaluation

The dBdx math function has been improved to reduce overflow.

2.12.3 Default Edge Model

The edge_index is now a default edge models created on a region Table 4.2.

2.13 August 14, 2013

2.13.1 SYMDIFF functions

The vec_max and vec_min functions have been added to the SYMDIFF parser (Table 10.2). The vec_sum function replaces sum.

2.13.2 Default Node Models

The coordinate_index and node_index are now part of the default node models created on a region (Table 4.1}).

2.13.3 Set Node Value

It is now possible to use the ds.set_node_value() (page 87) to set a uniform value or indexed value on a node model.

2.13.4 Fix Edge Average Model

Fixed issue with ds.edge_average_model() (page 79) during serialization to the DEVSIM format.

2.14 July 29, 2013

2.14.1 DEVSIM is open source

DEVSIM is now an open source project and is available from https://github.com/devsim/devsim. License information may be found in *DEVSIM License* (page 53). If you would like to participate in this project or need support, please contact us using the information in *Contact* (page 1). Installation instructions may be found in *Installation* (page 51).

2.14.2 Build

The Tcl interpreter version of DEVSIM is now called devsim_tcl, and is located in /src/main/ of the build directory. Please see the INSTALL file for more information.

2.14.3 Contact Material

Contacts now require a material setting (e.g. metal). This is for informational purposes. Contact models still look up parameter values based on the region they are located.

2.14.4 External Meshing

Please see *Using an external mesher* (page 34) for more information about importing meshes from other tools.

Genius **Mesh Import** DEVSIM can now read meshes written from Genius Device Simulator. More information about Genius is in *Genius* (page 34).

Gmsh **Mesh Import** DEVSIM reads version 2.1 and 2.2 meshes from Gmsh. Version 2.0 is no longer supported. Please see ref:*sec_gmshintro* for more information.

2.14.5 Math Functions

The acosh, asinh, atanh, are now available math functions. Please see Table 10.2.

2.14.6 Test directory structure

Platform specific results are stored in a hierarchical fashion.

2.14. July 29, 2013

Chapter 3

Introduction

3.1 Overview

DEVSIM is a technology computer-aided design (TCAD) software for semiconductor device simulation. While geared toward this application, it may be used where the control volume approach is appropriate for solving systems of partial-differential equations (PDE's) on a static mesh. After introducing DEVSIM, the rest of the manual discusses the key components of the system, and instructions for their use.

DEVSIM is available from https://www.devsim.org. The source code is available under the terms of the Apache License Version 2.0 [ApacheSoftwareFoundation] (page 111). Examples are released under the Apache License Version 2.0 [ApacheSoftwareFoundation] (page 111). Contributions to this project are welcome in the form of bug reporting, documentation, modeling, and feature implementation.

3.2 Goals

The primary goal of DEVSIM is to give the user as much flexibility and control as possible. In this regard, few models are coded into the program binary. They are implemented in human-readable scripts that can be modified if necessary.

DEVSIM is embedded within a scripting language interface (*User Interface* (page 39)). This provides control structures and language syntax in a consistent and intuitive manner. Taking a hierarchical approach, the user is provided an environment where they can implement new models on their own. This is without requiring extensive vendor support or use of compiled programming languages.

SYMDIFF (*SYMDIFF* (page 43)) is the symbolic expression parser used to allow the formulation of device equations in terms of models and parameters. Using symbolic differentiation, the required partial derivatives can be generated, or provided by the user. DEVSIM then assembles these equations over the mesh.

3.3 Structures

Devices A device refers to a discrete structure being simulated. It is composed of the following types of objects.

Regions A region defines a portion of the device of a specific material. Each region has its own system of equations being solved.

Interfaces Interfaces connect two regions together. At the interfaces, equations are specified to account for how the flux in each device region crosses the region boundary.

Contacts Contacts specify the boundary conditions required for device simulation. It also specifies how terminal currents are are integrated into an external circuit.

3.4 Equation assembly

Equation assembly of models is discussed in *Equation and Models* (page 15).

3.5 Parameters

Parameters may be specified globally, or for a specific device or region. Alternatively, parameters may be based on the material type of the regions. Usage is discussed in *Model Parameters* (page 29).

3.6 Circuits

Circuit boundary conditions allow multi-device simulation. They are also required for setting sources and their response for AC and noise analysis. Circuit elements, such as voltage sources, current sources, resistors, capacitors, and inductors may be specified. This is further discussed in *Circuits* (page 31).

3.7 Meshing

Meshing is discussed in *Meshing* (page 33).

3.8 Analysis

DEVSIM offers a range of simulation algorithms. They are discussed in more detail in *Solver* (page 37).

DC The DC operating point analysis is useful for performing steady-state simulation for a different bias conditions.

AC At each DC operating point, a small-signal AC analysis may be performed. An AC source is provided through a circuit and the response is then simulated. This is useful for both quasi-static capacitance simulation, as well as RF simulation.

Noise/Sensitivity Noise analysis may be used to evaluate how internal noise sources are observed in the terminal currents of the device or circuit. Using this method, it is also possible to simulate how the device response changes when device parameters are changed.

Transient DEVSIM is able to simulate the nonlinear transient behavior of devices, when the bias conditions change with time.

3.9 Scripting interface

The scripting interface to DEVSIM is discussed in *User Interface* (page 39).

3.10 Expression parser

The expression parser is discussed in *SYMDIFF* (page 43).

3.11 Visualization and postprocessing

Visualization is discussed in *Visualization* (page 49).

3.12 Installation

Installation is discussed in *Installation* (page 51).

3.13 Additional information

Additional information is discussed in *Additional Information* (page 53).

3.14 Examples

Examples are discussed in the remaining chapters beginning with *Example Overview* (page 93).

Chapter 4

Equation and Models

4.1 Overview

DEVSIM uses the control volume approach for assembling partial-differential equations (PDE's) on the simulation mesh. DEVSIM is used to solve equations of the form:

$$\frac{\partial X}{\partial t} + \nabla \cdot \vec{Y} + Z = 0$$

Internally, it transforms the PDE's into an integral form.

$$\int \frac{\partial X}{\partial t} \partial r + \int \vec{Y} \cdot \partial s + \int Z \partial r = 0$$

Equations involving the divergence operators are converted into surface integrals, while other components are integrated over the device volume.

In Fig. 4.1, 2D mesh elements are depicted. The shaded area around the center node is referred to as the node volume, and it is used for the volume integration. The lines from the center node to other nodes are referred to as edges. The flux through the edge are integrated with respect to the perpendicular bisectors (dashed lines) crossing each triangle edge.

In this form, we refer to a model integrated over the edges of triangles as edge models. Models integrated over the volume of each triangle vertex are referred to as node models. Element edge models are a special case where variables at other nodes off the edge may cause the flux to change.

There are a default set of models created in each region upon initialization of a device, and are typically based on the geometrical attributes. These are described in the following sections. Models required for describing the device behavior are created using the equation parser described in *SYMDIFF* (page 43). For special situations, custom matrix assembly is also available and is discussed in *Custom matrix assembly* (page 26).

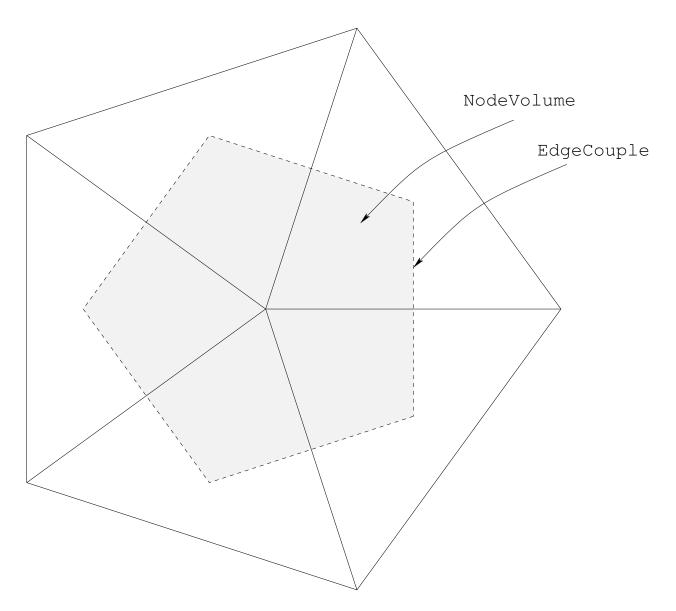


Fig. 4.1: Mesh elements in 2D.

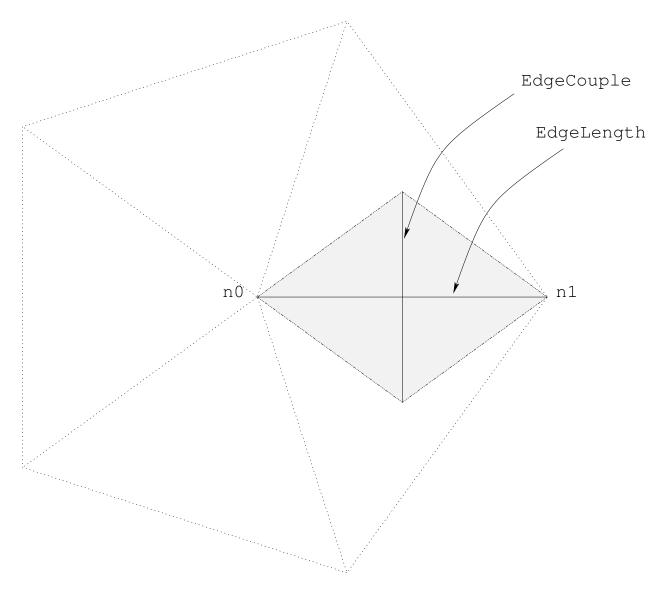


Fig. 4.2: Edge model constructs in 2D.

4.1. Overview

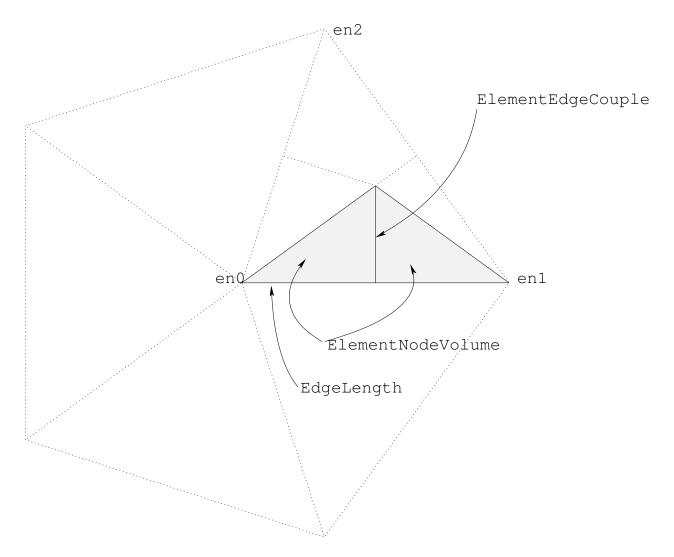


Fig. 4.3: Element edge model constructs in 2D.

4.2 Bulk models

4.2.1 Node models

Node models may be specified in terms of other node models, mathematical functions, and parameters on the device. The simplest model is the node solution, and it represents the solution variables being solved for. Node models automatically created for a region are listed in Table 4.1.

In this example, we present an implementation of Shockley Read Hall recombination [MKC02] (page 111).

The first model specified, USRH, is the recombination model itself. The derivatives with respect to electrons and holes are USRH: Electrons and USRH: Holes, respectively. In this particular example Electrons and Holes have already been defined as solution variables. The remaining variables in the equation have already been specified as parameters.

The diff function tells the equation parser to take the derivative of the original expression, with respect to the variable specified as the second argument. During equation assembly, these derivatives are required in order to converge upon a solution. The simplify function tells the expression parser to attempt to simplify the expression as much as possible.

Node Model	Description	
AtContactNode	Evaluates to 1 if node is a contact node, otherwise 0	
NodeVolume	The volume of the node. Used for volume integration of node models on nodes	
	in mesh	
NSurfaceNormal_x	The surface normal to points on the interface or contact (2D and 3D)	
NSurfaceNormal_y	ormal_y The surface normal to points on the interface or contact (2D and 3D)	
NSurfaceNormal_z The surface normal to points on the interface or contact (3D)		
SurfaceArea	faceArea The surface area of a node on interface and contact nodes, otherwise 0	
coordinate_index Coordinate index of the node on the device		
node_index	node_index Index of the node in the region	
Х	x position of the node	
У	y position of the node	
Z	z position of the node	

Table 4.1: Node models defined on each region of a device.

4.2. Bulk models

4.2.2 Edge models

Edge models may be specified in terms of other edge models, mathematical functions, and parameters on the device. In addition, edge models may reference node models defined on the ends of the edge. As depicted in Fig. 4.2, edge models are with respect to the two nodes on the edge, n0 and n1.

For example, to calculate the electric field on the edges in the region, the following scheme is employed:

In this example, EdgeInverseLength is a built-in model for the inverse length between nodes on an edge. Potential@n0 and Potential@n1 is the Potential node solution on the nodes at the end of the edge. These edge quantities are created using the <code>ds.edge_from_node_model()</code> (page 80). In addition, the <code>ds.edge_average_model()</code> (page 79) can be used to create edge models in terms of node model quantities.

Edge models automatically created for a region are listed in Table 4.2.

Edge Model	Description		
EdgeCouple	The length of the perpendicular bisector of an element edge. Used to perform		
	surface integration of edge models on edges in mesh.		
EdgeInverseL	EdgeInverseLehnyense of the EdgeLength.		
EdgeLength	The distance between the two nodes of an edge		
edge_index	Index of the edge on the region		
unitx	x component of the unit vector along an edge		
unity	y component of the unit vector along an edge (2D and 3D)		
unitz	z component of the unit vector along an edge (3D only)		

Table 4.2: Edge models defined on each region of a device.

4.2.3 Element edge models

Element edge models are used when the edge quantitites cannot be specified entirely in terms of the quantities on both nodes of the edge, such as when the carrier mobility is dependent on the normal electric field. In 2D, element edge models are evaluated on each triangle edge. As depicted in Fig. 4.3, edge models are with respect to the three nodes on each triangle edge and are denoted as en0, en1, and en2. Derivatives are with respect to each node on the triangle.

In 3D, element edge models are evaluated on each tetrahedron edge. Derivatives are with respect to the nodes on both triangles on the tetrahedron edge. Element edge models automatically created for a region are listed in Table 4.3.

As an alternative to treating integrating the element edge model with respect to ElementEdgeCouple, the integration may be performed with respect to ElementNodeVolume. See <code>ds.equation()</code> (page 61) for more information.

Table 4.3: Element edge models defined on each region of a device.

Element Edge	Description
Model	
ElementEdge	The length of the perpendicular bisector of an edge. Used to perform surface
	integration of element edge model on element edge in the mesh.
ElementNode	√Themode volume at either end of each element edge.

4.2.4 Model derivatives

To converge upon the solution, derivatives are required with respect to each of the solution variables in the system. DEVSIM will look for the required derivatives. For a model model, the derivatives with respect to solution variable variable are presented in Table 4.4.

Table 4.4: Required derivatives for equation assembly. model is the name of the model being evaluated, and variable is one of the solution variables being solved at each node.

Model Type	Derivatives Required		
Node Model	Node Model model:variable		
Edge Model	model:variable@n0 model:variable@n1		
Element Edge model:variable@en0 model:variable@en1 model:variable@en2			
Model	model:variable@en3(3D)		

4.2.5 Conversions between model types

The <code>ds.edge_from_node_model()</code> (page 80) is used to create edge models referring to the nodes connecting the edge. For example, the edge models <code>Potential@n0</code> and <code>Potential@n1</code> refer to the <code>Potential</code> node model on each end of the edge.

The ds.edge_average_model() (page 79) creates an edge model which is either the arithmetic mean, geometric mean, gradient, or negative of the gradient of the node model on each edge.

When an edge model is referred to in an element edge model expression, the edge values are implicitly converted into element edge values during expression evaluation. In addition, derivatives of the edge model with respect to the nodes of an element edge are required, they are converted as well. For example, edgemodel:variable@n0 and edgemodel:variable@n1 are implicitly converted to edgemodel:variable@en0 and edgemodel:variable@en1, respectively.

The <code>ds.element_from_edge_model()</code> (page 81) is used to create directional components of an edge model over an entire element. The <code>derivative</code> option is used with this command to create the derivatives with respect to a specific node model. The <code>ds.element_from_node_model()</code> (page 83) is used to create element edge models referring to each node on the element of the element edge.

4.2. Bulk models 21

4.2.6 Equation assembly

Bulk equations are specified in terms of the node, edge, and element edge models using the ds. equation() (page 61). Node models are integrated with respect to the node volume. Edge models are integrated with the perpendicular bisectors along the edge onto the nodes on either end.

Element edge models are treated as flux terms and are integrated with respect to ElementEdgeCouple using the element_model option. Alternatively, they may be treated as source terms and are integrated with respect to ElementNodeVolume using the volume_model option.

In this example, we are specifying the Potential Equation in the region to consist of a flux term named PotentialEdgeFlux and to not have any node volume terms.

```
ds.equation(device="device", region="region", name="PotentialEquation",
   variable_name="Potential", edge_model="PotentialEdgeFlux",
   variable_update="log_damp" )
```

In addition, the solution variable coupled with this equation is Potential and it will be updated using logarithmic damping.

Table 4.5: Required derivatives for interface equation assembly. The node model name nodemodel and its derivatives nodemodel:variable are suffixed with @r0 and @r1 to denote which region on the interface is being referred to.

Model Type	Model Name	Derivatives Required
Node Model (region	nodemodel@r0	nodemodel:variable@r0
0)		
Node Model (region	nodemodel@r1	nodemodel:variable@r1
1)		
Interface Node	inodemodel	inodemodel:variable@r0
Model		inodemodel:variable@r1

4.3 Interface

4.3.1 Interface models

Fig. 4.4 depicts an interface in DEVSIM. It is a collection of overlapping nodes existing in two regions, r0 and r1.

Interface models are node models specific to the interface being considered. They are unique from bulk node models, in the sense that they may refer to node models on both sides of the interface. They are specified using the <code>ds.interface_model()</code> (page 85). Interface models may refer to node models or parameters on either side of the interface using the syntax nodemodel@r0 and nodemodel@r1 to refer to the node model in the first and second regions of the interface. The naming convention for node models, interface node models, and their derivatives are shown in Table 4.5.

```
ds.interface_model(device="device", interface="interface",
    name="continuousPotential", equation="Potential@r0-Potential@r1")
```

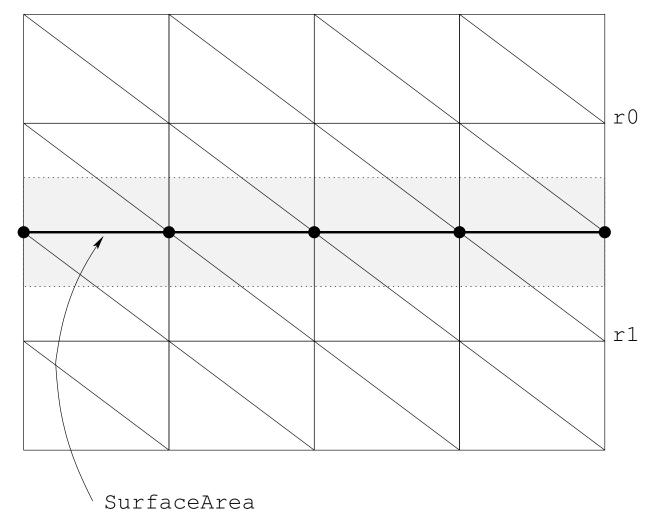


Fig. 4.4: Interface constructs in 2D. Interface node pairs are located at each \bullet . The SurfaceArea model is used to integrate flux term models.

4.3. Interface 23

4.3.2 Interface model derivatives

For a given interface model, model, the derivatives with respect to the variable variable in the regions are

- model:variable@r0
- model:variable@r1

```
ds.interface_model(device="device", interface="interface",
   name="continuousPotential:Potential@r0", equation="1")
ds.interface_model(device="device", interface="interface",
   name="continuousPotential:Potential@r1", equation="-1")
```

4.3.3 Interface equation assembly

There are two types of interface equations considered in DEVSIM. They are both activated using the *ds*. interface_equation() (page 63).

In the first form, continuous, the equations for the nodes on both sides of the interface are integrated with respect to their volumes and added into the same equation. An additional equation is then specified to relate the variables on both sides. In this example, continuity in the potential solution across the interface is enforced, using the continuousPotential model defined in the previous section.

In the second form, fluxterm, a flux term is integrated over the surface area of the interface and added to the first region, and subtracted from the second.

4.4 Contact

4.4.1 Contact models

Fig. 4.5 depicts how a contact is treated in a simulation. It is a collection of nodes on a region. During assembly, the specified models form an equation, which replaces the equation applied to these nodes for a bulk node.

Contact models are equivalent to node and edge models, and are specified using the ds. contact_node_model() (page 76) and the ds.contact_edge_model() (page 76), respectively. The key difference is that the models are only evaluated on the contact nodes for the contact specified.

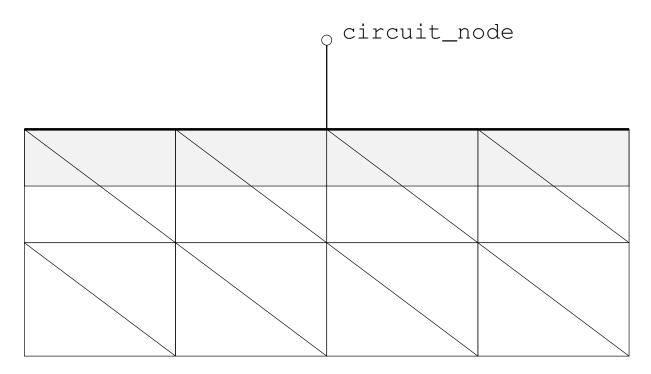


Fig. 4.5: Contact constructs in 2D.

4.4.2 Contact model derivatives

The derivatives are equivalent to the discussion in *Model derivatives* (page 21). If external circuit boundary conditions are being used, the model model derivative with respect to the circuit node node name should be specified as model:node.

4.4.3 Contact equation assembly

The ds.contact_equation() (page 59) is used to specify the boundary conditions on the contact nodes. The models specified replace the models specified for bulk equations of the same name. For example, the node model specified for the contact equation is assembled on the contact nodes, instead of the node model specified for the bulk equation. Contact equation models not specified are not assembled, even if the model exists on the bulk equation for the region attached to the contact.

As an example

Current models refer to the instantaneous current flowing into the device. Charge models refer to the instantaneous charge at the contact.

During a transient, small-signal or ac simulation, the time derivative is taken so that the net current into a

4.4. Contact 25

circuit node is

$$I(t) = i(t) + \frac{\partial q(t)}{\partial t}$$

where i is the integrated current and q is the integrated charge.

4.5 Custom matrix assembly

The ds.custom_equation() (page 60) command is used to register callbacks to be called during matrix and right hand side assembly. The Python procedure must expect to receive two arguments and return two lists. For example a procedure named myassemble registered with

```
ds.custom_equation(name="test1", procedure="myassemble")
```

must expect to receive two arguments

```
def myassemble(what, timemode):
   .
   .
   return [rcv, rv]
```

where what may be passed as one of

MATRIXONLY

RHS

MATRIXANDRHS

and timemode may be passed as one of

DC

TIME

When timemode is DC, the time-independent part of the equation is returned. When timemode is TIME, the time-derivative part of the equation is returned. The simulator will scale the time-derivative terms with the proper frequency or time scale.

The return value from the procedure must return two lists of the form

```
[1 1 1.0 2 2 1.0 1 2 -1.0 2 1 -1.0 2 2 1.0] [1 1.0 2 1.0 2 -1.0]
```

where the length of the first list is divisible by 3 and contains the row, column, and value to be assembled into the matrix. The second list is divisible by 2 and contains the right-hand side entries. Either list may be empty.

The ds.get_circuit_equation_number() (page 58) may be used to get the equation numbers corresponding to circuit node names. The ds.get_equation_numbers() (page 63) may be used to find the equation number corresponding to each node index in a region.

The matrix and right hand side entries should be scaled by the NodeVolume if they are assembled into locations in a device region. Row permutations, required for contact and interface boundary conditions, are automatically applied to the row numbers returned by the Python procedure.

4.6 Cylindrical Coordinate Systems

In 2D, models representing the edge couples, surface areas and node volumes may be generated using the following commands:

- ds.cylindrical_edge_couple() (page 77)
- ds.cylindrical_node_volume() (page 77)
- ds.cylindrical_surface_area() (page 78)

In order to change the integration from the default models to cylindrical models, the following parameters may be set

```
set_parameter(name="node_volume_model",
    value="CylindricalNodeVolume")
set_parameter(name="edge_couple_model",
    value="CylindricalEdgeCouple")
set_parameter(name="edge_node0_volume_model",
    value="CylindricalEdgeNodeVolume@n0")
set_parameter(name="edge_node1_volume_model",
    value="CylindricalEdgeNodeVolume@n1")
set_parameter(name="element_edge_couple_model",
    value="ElementCylindricalEdgeCouple")
set_parameter(name="element_node0_volume_model",
    value="ElementCylindricalNodeVolume@en0")
set_parameter(name="element_node1_volume_model",
    value="ElementCylindricalNodeVolume@en0")
```

Chapter 5

Model Parameters

Parameters can be set using the commands in *Material Commands* (page 65). There are two complementary formalisms for doing this.

5.1 Parameters

Parameters are set globally, on devices, or on regions of a device. The models on each device region are automatically updated whenever parameters change.

```
ds.set_parameter(device="device", region="region",
  name="ThermalVoltage", value=0.0259)
```

5.2 Material database entries

Alternatively, parameters may be set based on material types. A database file is used for getting values on the regions of the device.

```
ds.create_db(filename="foodb")
ds.add_db_entry(material="global", parameter="q", value=1.60217646e-19,
    unit="coul", description="Electron Charge")
ds.add_db_entry(material="Si", parameter="one",
    value=1, unit="", description="")
ds.close_db
```

When a database entry is not available for a specific material, the parameter will be looked up on the global material entry.

5.3 Discussion

Both parameters and material database entries may be used in model expressions. Parameters have precedence in this situation. If a parameter is not found, then DEVSIM will also look for a circuit node by the

name used in the model expression.

Circuits

6.1 Circuit elements

Circuit elements are manipulated using the commands in *Circuit Commands* (page 57). Using the *ds.circuit_element* () (page 57) to add a circuit element will implicitly create the nodes being references.

A simple resistor divider with a voltage source would be specified as:

```
ds.circuit_element(name="V1", n1="1", n2="0", value=1.0)
ds.circuit_element(name="R1", n1="1", n2="2", value=5.0)
ds.circuit_element(name="R2", n1="2", n2="0", value=5.0)
```

Circuit nodes are created automatically when referred to by these commands. Voltage sources create an additional circuit node of the form V1.I to account for the current flowing through it.

6.2 Connecting devices

For devices to contribute current to an external circuit, the <code>ds.contact_equation()</code> (page 59) should use the <code>circuitnode</code> option to specify the circuit node in which to integrate its current. This option does not create a node in the circuit. No circuit boundary condition for the contact equation will exist if the circuit node does not actually exist in the circuit. The <code>ds.circuit_node_alias()</code> (page 58) may be used to associate the name specified on the contact equation to an existing circuit node on the circuit.

The circuit node names may be used in any model expression on the regions and interfaces. However, the simulator will only take derivatives with respect to circuit nodes names on models used to compose the contact equation.

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Meshing

7.1 1D mesher

DEVSIM has an internal 1D mesher and the proper sequence of commands follow in this example.

```
ds.create_1d_mesh (mesh="cap")
ds.add_1d_mesh_line (mesh="cap", pos=0, ps=0.1, tag="top")
ds.add_1d_mesh_line (mesh="cap", pos=0.5, ps=0.1, tag="mid")
ds.add_1d_mesh_line (mesh="cap", pos=1, ps=0.1, tag="bot")
ds.add_1d_contact (mesh="cap", name="top", tag="top", material="metal")
ds.add_1d_contact (mesh="cap", name="bot", tag="bot", material="metal")
ds.add_1d_interface (mesh="cap", name="MySiox", tag="mid")
ds.add_1d_region (mesh="cap", material="Si", region="MySiRegion",
    tag1="top", tag2="mid")
ds.add_1d_region (mesh="cap", material="Ox", region="MyOxRegion",
    tag1="mid", tag2="bot")
ds.finalize_mesh (mesh="cap", device="device")
```

The ds.create_1d_mesh() (page 73) is first used to initialize the specification of a new mesh by the name specified with the command option. The ds.add_1d_mesh_line() (page 68) is used to specify the end points of the 1D structure, as well as the location of points where the spacing changes. The command is used to create reference labels used for specifying the contacts, interfaces and regions.

The ds.add_1d_contact() (page 68), ds.add_1d_interface() (page 68) and ds.add_1d_region() (page 69) are used to specify the contacts, interfaces and regions for the device.

Once the meshing commands have been completed, the <code>ds.finalize_mesh()</code> (page 75) is called to create a mesh structure and then <code>ds.create_device()</code> (page 74) is used to create a device using the mesh.

7.2 2D mesher

Similar to the 1D mesher, the 2D mesher uses a sequence of non-terminating mesh lines are specified in both the x and y directions to specify a mesh structure. As opposed to using tags, the regions are specified

using ds.add_2d_region() (page 71) as box coordinates on the mesh coordinates. The contacts and interfaces are specified using boxes, however it is best to ensure the interfaces and contacts encompass only one line of points.

```
ds.create_2d_mesh(mesh="cap")
ds.add_2d_mesh_line(mesh="cap", dir="y", pos=-0.001, ps=0.001)
ds.add_2d_mesh_line(mesh="cap", dir="x", pos=xmin, ps=0.1)
ds.add 2d mesh line (mesh="cap", dir="x", pos=xmax, ps=0.1)
ds.add_2d_mesh_line(mesh="cap", dir="y", pos=ymin, ps=0.1)
ds.add_2d_mesh_line(mesh="cap", dir="y", pos=ymax, ps=0.1)
ds.add_2d_mesh_line(mesh="cap", dir="y", pos=+1.001, ps=0.001)
ds.add_2d_region(mesh="cap", material="gas", region="gas1", yl=-.001, yh=0.0)
ds.add_2d_region(mesh="cap", material="gas", region="gas2", yl=1.0, yh=1.001)
ds.add_2d_region(mesh="cap", material="Oxide", region="r0", xl=xmin, xh=xmax,
 yl=ymid1, yh=ymin)
ds.add_2d_region(mesh="cap", material="Silicon", region="r1", xl=xmin,_
\rightarrowxh=xmax,
 yl=ymid2, yh=ymid1)
ds.add_2d_region(mesh="cap", material="Silicon", region="r2", xl=xmin,...
\rightarrowxh=xmax,
 yl=ymid2, yh=ymax)
ds.add_2d_interface(mesh="cap", name="i0", region0="r0", region1="r1")
ds.add_2d_interface(mesh="cap", name="i1", region0="r1", region1="r2",
  xl=0, xh=1, yl=ymid2, yh=ymid2, bloat=1.0e-10)
ds.add_2d_contact(mesh="cap", name="top", region="r0", yl=ymin, yh=ymin,
 bloat=1.0e-10, material="metal")
ds.add_2d_contact(mesh="cap", name="bot", region="r2", yl=ymax, yh=ymax,
 bloat=1.0e-10, material="metal")
ds.finalize_mesh(mesh="cap")
ds.create_device(mesh="cap", device="device")
```

In the current implementation of the software, it is necessary to create a region on both sides of the contact in order to create a contact using <code>ds.add_2d_contact()</code> (page 69) or an interface using <code>ds.add_2d_interface()</code> (page 70).

Once the meshing commands have been completed, the <code>ds.finalize_mesh()</code> (page 75) is called to create a mesh structure and then <code>ds.create_device()</code> (page 74) is used to create a device using the mesh.

7.3 Using an external mesher

DEVSIM supports reading meshes from Genius Device Simulator and Gmsh. These meshes may only contain points, lines, triangles, and tetrahedra. Hybrid meshes or uniform meshes containing other elements are not supported at this time.

7.3.1 Genius

Meshes from the Genius Device Simulator software (see *Genius* (page 53)) can be imported using the CGNS format. In this example, ds.create_genius_mesh() (page 74) returns region and boundary

information which can be used to setup the device.

```
mesh_name = "nmos_iv"
result = create_genius_mesh(file="nmos_iv.cgns", mesh=mesh_name)
contacts = \{\}
for region_name, region_info in result['mesh_info']['regions'].iteritems():
  add_genius_region(mesh=mesh_name, genius_name=region_name,
                   region=region_name, material=region_info['material'])
  for boundary, is_electrode in region_info['boundary_info'].iteritems():
    if is electrode:
      if boundary in contacts:
        contacts[boundary].append(region_name)
      else:
        contacts[boundary] = [region_name, ]
for contact, regions in contacts.iteritems():
  if len(regions) == 1:
    add_genius_contact(mesh=mesh_name, genius_name=contact, name=contact,
      region=regions[0], material='metal')
  else:
    for region in regions:
      add_genius_contact(mesh=mesh_name, genius_name=contact,
        name=contact+'@'+region, region=region, material='metal')
for boundary name, regions in result['mesh info']['boundaries'].iteritems():
  if (len(regions) == 2):
    add_genius_interface(mesh=mesh_name, genius_name=boundary_name,
      name=boundary_name, region0=regions[0], region1=regions[1])
finalize_mesh (mesh=mesh_name)
create_device(mesh=mesh_name, device=mesh_name)
```

Example locations are available on *genius* (page 93).

7.3.2 Gmsh

The Gmsh meshing software (see *Gmsh* (page 53)) can be used to create a 1D, 2D, or 3D mesh suitable for use in DEVSIM. When creating the mesh file using the software, use physical group names to map the difference entities in the resulting mesh file to a group name. In this example, a mos structure is read in:

```
ds.create_gmsh_mesh(file="gmsh_mos2d.msh", mesh="mos2d")
ds.add_gmsh_region(mesh="mos2d" gmsh_name="bulk", region="bulk",
    material="Silicon")
ds.add_gmsh_region(mesh="mos2d" gmsh_name="oxide", region="oxide",
    material="Silicon")
ds.add_gmsh_region(mesh="mos2d" gmsh_name="gate", region="gate",
    material="Silicon")
ds.add_gmsh_contact(mesh="mos2d" gmsh_name="drain_contact", region="bulk",
    name="drain", material="metal")
```

Once the meshing commands have been completed, the <code>ds.finalize_mesh()</code> (page 75) is called to create a mesh structure and then <code>ds.create_device()</code> (page 74) is used to create a device using the mesh.

7.4 Loading and saving results

The <code>ds.write_devices()</code> (page 76) is used to create an ASCII file suitable for saving data for restarting the simulation later. The <code>devsim</code> format encodes structural information, as well as the commands necessary for generating the models and equations used in the simulation. The <code>devsim_data</code> format is used for storing numerical information for use in other programs for analysis. The <code>ds.load_devices()</code> (page 75) is then used to reload the device data for restarting the simulation.

Solver

8.1 Solver

DEVSIM uses Newton methods to solve the system of PDE's. All of the analyses are performed using the ds.solve() (page 90).

8.2 DC analysis

A DC analysis is performed using the ds.solve() (page 90).

```
solve(type="dc", absolute_error=1.0e10, relative_error=1e-7 maximum_

→iterations=30)
```

8.3 AC analysis

An AC analysis is performed using the ds.solve() (page 90). A circuit voltage source is required to set the AC source.

8.4 Noise/Sensitivity analysis

An noise analysis is performed using the ds.solve() (page 90) command. A circuit node is specified in order to find its sensitivity to changes in the bulk quantities of each device. If the circuit node is named V1.I. A noise simulation is performed using:

```
solve(type="noise", frequency=1e5, output_node="V1.I")
```

Noise and sensitivity analysis is performed using the <code>ds.solve()</code> (page 90). If the equation begin solved is PotentialEquation, the names of the scalar impedance field is then:

• V1.I_PotentialEquation_real

• V1.I_PotentialEquation_imag

and the vector impedance fields evaluated on the nodes are

- V1.I_PotentialEquation_real_gradx
- V1.I_PotentialEquation_imag_gradx
- V1.I_PotentialEquation_real_grady (2D and 3D)
- V1.I_PotentialEquation_imag_grady (2D and 3D)
- V1.I_PotentialEquation_real_gradz (3D only)
- V1.I_PotentialEquation_imag_gradz (3D only)

8.5 Transient analysis

Transient analysis is performed using the ds.solve() (page 90). DEVSIM supports time-integration of the device PDE's. The three methods are supported are:

- BDF1
- TRBDF
- BDF2

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User Interface

9.1 Starting DEVSIM

Refer to *Installation* (page 51) for instructions on how to install DEVSIM. Once installed, DEVSIM may be invoked using the following command

devsim

for an interactive shell or

devsim filename.py

for batch mode where filename.py is the name of script being run. DEVSIM output is printed to the screen. To capture the output of the program, shell redirection commands may be used to direct the output to a file.

9.2 Python Language

9.2.1 Introduction

Python is the scripting language employed as the text interface to DEVSIM. Documentation and tutorials for the language are available from [pyt] (page 111). A paper discussing the general benefits of using scripting languages may be found in [Ous98] (page 111).

9.2.2 DEVSIM commands

All of commands are in the ds namespace. In order to invoke a command, the command should be prefixed with ds., or the following may be placed at the beginning of the script:

from ds import *

For details concerning error handling, please see *Error handling* (page 40).

9.3 Other packages

DEVSIM is able to load Python packages. It is important to note that binary extensions loaded into DEVSIM must be compatible with the operating system which it was compiled for. To load an extension, it is first necessary to provide the path as an environment variable, or at program run time.

For example, if the Python packages on your system are available in /usr/share/tcltk, it is necessary to set the environment variable in csh as

```
setenv PYTHONPATH /usr/share/tcltk
```

or in bash

```
export PYTHONPATH=/usr/share/tcltk
```

In the Python script, this may be done using using the appropriate paths for your system

```
import sys
sys.path.append("/usr/share/tcltk")
```

Please see *Python* (page 54) for more information on obtaining a copy of Python for your computer's operating system.

9.3.1 Advanced usage

In this manual, more advanced usage of the Python language may be used. The reader is encouraged to use a suitable reference to clarify the proper use of the scripting language constructs, such as control structures.

9.3.2 Unicode Support

Internally, DEVSIM uses UTF-8 encoding, and expects model equations and saved mesh files to be written using this encoding. Users are encouraged to use the standard ASCII character set if they do not wish to use this feature. When reading a unicode encoded script, the built in Python interpreter should be made aware of the encoding of the source encoding using this on the first or second line of the script

```
# -*- coding: utf-8 -*-
```

This option is only required on systems, such as Microsoft Windows, which do not default to this encoding. Care should be taken when using unicode names for visualization using the tools in *Visualization* (page 49), as this character set may not be supported.

9.4 Error handling

9.4.1 Python errors

When a syntax error occurs in a Python script an exception may be thrown. If it is uncaught, then DEVSIM will terminate. More details may be found in an appropriate reference. An exception that is thrown by

DEVSIM is of the type ds.error. It may be caught.

9.4.2 Fatal errors

When DEVSIM enters a state in which it may not recover. The interpreter should throw a Python exception with a message DEVSIM FATAL. At this point DEVSIM may enter an inconsistent state, so it is suggested not to attempt to continue script execution if this occurs.

In rare situations, the program may behave in an erratic manner, print a message, such as UNEXPECTED or terminate abruptly. Please report this to DEVSIM LLC using the contact information in *Contact* (page 1).

9.4.3 Floating point exceptions

During model evaluation, DEVSIM will attempt to detect floating point issues and return an error with some diagnostic information printed to the screen, such as the symbolic expression being evaluated. Floating point errors may be characterized as invalid, division by zero, and numerical overflow. This is considered to be a fatal error.

9.4.4 Solver errors

When using the ds.solve() (page 90), the solver may not converge and a message will be printed and an exception may be thrown. The solution will be restored to its previous value before the simulation began. This exception may be caught and the bias conditions may be changed so the simulation may be continued. For example:

```
try:
    solve(type="dc", absolute_error=abs_error,
        relative_error=rel_error, maximum_iterations=max_iter)
except ds.error as msg:
    if msg[0].find("Convergence failure") != 0:
        raise
    #### put code to modify step here.
```

9.4.5 Verbosity

The set_parameter() may be used to set the verbosity globally, per device, or per region. Setting the debug_level parameter to info results in the default level of information to the screen. Setting this option to verbose or any other name results in more information to the screen which may be useful for debugging.

The following example sets the default level of debugging for the entire simulation, except that the gate region will have additional debugging information.

```
ds.set_parameter(name="debug_level", value="info")
ds.set_parameter(device="device" region="gate",
    name="debug_level", value="verbose")
```

9.4.6 Parallelization

Routines for the evaluating of models have been parallelized. In order to select the number of threads to use

```
ds.set_parameter(name="threads_available", value=2)
```

where the value specified is the number of threads to be used. By default, DEVSIM does not use threading. For regions with a small number of elements, the time for switching threads is more than the time to evaluate in a single thread. To set the minimum number of elements for a calculation, set the following parameter.

```
ds.set_parameter(name="threads_task_size", value=1024)
```

SYMDIFF

10.1 Overview

SYMDIFF is a tool capable of evaluating derivatives of symbolic expressions. Using a natural syntax, it is possible to manipulate symbolic equations in order to aid derivation of equations for a variety of applications. It has been tailored for use within DEVSIM.

10.2 Syntax

10.2.1 Variables and numbers

Variables and numbers are the basic building blocks for expressions. A variable is defined as any sequence of characters beginning with a letter and followed by letters, integer digits, and the _ character. Note that the letters are case sensitive so that a and {A} are not the same variable. Any other characters are considered to be either mathematical operators or invalid, even if there is no space between the character and the rest of the variable name.

Examples of valid variable names are:

Numbers can be integer or floating point. Scientific notation is accepted as a valid syntax. For example:

10.2.2 Basic expressions

Table 10.1: Basic expressions involving unary, binary, and logical operators.

Expression	Description
(exp1)	Parenthesis for changing precedence
+exp1	Unary Plus
-exp1	Unary Minus
!exp1	Logical Not
exp1 ^ exp2	Exponentiation
exp1 * exp2	Multiplication
exp1 / exp2	Division
exp1 + exp2	Addition
exp1 - exp2	Subtraction
exp1 < exp2	Test Less
exp1 <= exp2	Test Less Equal
exp1 > exp2	Test Greater
exp1 >= exp2	Test Greater Equal
exp1 == exp2	Test Equality
exp1 != exp2	Test Inequality
exp1 && exp2	Logical And
exp1 exp2	Logical Or
variable	Independent Variable
number	Integer or decimal number

In Table 10.1, the basic syntax for the language is presented. An expression may be composed of variables and numbers tied together with mathematical operations. Order of operations is from bottom to top in order of increasing precedence. Operators with the same level of precedence are contained within horizontal lines.

In the expression $a + b \star c$, the multiplication will be performed before the addition. In order to override this precedence, parenthesis may be used. For example, in $(a + b) \star c$, the addition operation is performed before the multiplication.

The logical operators are based on non zero values being true and zero values being false. The test operators are evaluate the numerical values and result in 0 for false and 1 for true.

It is important to note since values are based on double precision arithmetic, testing for equality with values other than 0.0 may yield unexpected results.

10.2.3 Functions

Table 10.2: Predefined Functions.

Function	Description
acosh(exp1)	Inverse Hyperbolic Cosine
asinh(exp1)	Inverse Hyperbolic Sine
atanh(exp1)	Inverse Hyperbolic Tangent
B(exp1)	Bernoulli Function
dBdx(exp1)	derivative of Bernoulli function
derfcdx(exp1)	derivative of complementary error function
derfdx(exp1)	derivative error function
dFermidx(exp1)	derivative of Fermi Integral
dInvFermidx(exp1)	derivative of InvFermi Integral
dot2d(exp1x, exp1y, exp2x,	exp1x*exp2x+exp1y*exp2y
exp2y)	
erfc(exp1)	complementary error function
erf(exp1)	error function
exp(exp1)	exponent
Fermi(exp1)	Fermi Integral
ifelse(test, exp1, exp2)	if test is true, then evaluate exp1, otherwise exp2
if(test, exp)	if test is true, then evaluate exp, otherwise 0
InvFermi(exp1)	inverse of the Fermi Integral
log(exp1)	natural log
max(exp1, exp2)	maximum of the two arguments
min(exp1, exp2)	minimum of the two arguments
pow(exp1, exp2)	take exp1 to the power of exp2
sgn(exp1)	sign function
step(exp1)	unit step function
kahan3(exp1, exp2, exp3)	Extended precision addition of arguments
kahan4(exp1, exp2, exp3, exp4)	Extended precision addition of arguments
vec_max	maximum of all the values over the entire region or
	interface
vec_min	minimum of all the values over the entire region or
	interface
vec_sum	sum of all the values over the entire region or interface

In Table 10.2 are the built in functions of SYMDIFF. Note that the pow function uses the , operator to separate arguments. In addition an expression like pow (a, b+y) is equivalent to an expression like a^ (b+y). Both exp and log are provided since many derivative expressions can be expressed in terms of these two functions. It is possible to nest expressions within functions and vice-versa.

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10.2.4 Commands

Table 10.3: Commands.

Command	Description
diff(obj1, var)	Take derivative of obj1 with respect to variable var
expand(obj)	Expand out all multiplications into a sum of products
help	Print description of commands
scale(obj)	Get constant factor
sign(obj)	Get sign as 1 or -1
simplify(obj)	Simplify as much as possible
subst(obj1,obj2,obj3)	substitute obj3 for obj2 into obj1
unscaledval(obj)	Get value without constant scaling
unsignedval(obj)	Get unsigned value

Commands are shown in Table 10.3. While they appear to have the same form as functions, they are special in the sense that they manipulate expressions and are never present in the expression which results. For example, note the result of the following command

```
> diff(a*b, b)
a
```

10.2.5 User functions

Table 10.4: Commands for user functions.

Command	Description
clear(name)	Clears the name of a user function
declare(name(arg1, arg2,	declare function name taking dummy arguments arg1,
))	arg2, Derivatives assumed to be 0
define(name(arg1, arg2,	declare function name taking arguments arg1, arg2,
), obj1, obj2,)	having corresponding derivatives obj1, obj2,

Commands for specifying and manipulating user functions are listed in Table 10.4. They are used in order to define new user function, as well as the derivatives of the functions with respect to the user variables. For example, the following expression defines a function named f which takes one argument.

```
> define(f(x), 0.5*x)
```

The list after the function protoype is used to define the derivatives with respect to each of the independent variables. Once defined, the function may be used in any other expression. In additions the any expression can be used as an arguments. For example:

```
> diff(f(x*y),x)
((0.5 * (x * y)) * y)
> simplify((0.5 * (x * y)) * y)
(0.5 * x * (y^2))
```

The chain rule is applied to ensure that the derivative is correct. This can be expressed as

$$\frac{\partial}{\partial x} f(u, v, \ldots) = \frac{\partial u}{\partial x} \cdot \frac{\partial}{\partial u} f(u, v, \ldots) + \frac{\partial v}{\partial x} \cdot \frac{\partial}{\partial v} f(u, v, \ldots) + \ldots$$

The declare command is required when the derivatives of two user functions are based on one another. For example:

```
> declare(cos(x))
cos(x)
> define(sin(x),cos(x))
sin(x)
> define(cos(x),-sin(x))
cos(x)
```

When declared, a functions derivatives are set to 0, unless specified with a define command. It is now possible to use these expressions as desired.

```
 > diff(sin(cos(x)),x) 

 (cos(cos(x)) * (-sin(x))) 

 > simplify(cos(cos(x)) * (-sin(x))) 

 (-cos(cos(x)) * sin(x))
```

10.2.6 Macro assignment

The use of macro assignment allows the substitution of expressions into new expressions. Every time a command is successfully used, the resulting expression is assigned to a special macro definition, \$_.

In this example, the result of the each command is substituted into the next.

```
> a+b
(a + b)
> $_-b
((a + b) - b)
> simplify($_)
```

In addition to the default macro definition, it is possible to specify a variable identifier by using the \$ character followed by an alphanumeric string beginning with a letter. In addition to letters and numbers, a _ character may be used as well. A macro which has not previously assigned will implicitly use 0 as its value.

This example demonstrates the use of macro assignment.

```
> a1 = a + b

a + b

> a2 = a - b

a - b

> simplify(a1 + a2)

a + a2
```

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10.3 Invoking SYMDIFF from DEVSIM

10.3.1 Equation parser

The ds.symdiff() (page 88) should be used when defining new functions to the parser. Since you do not specify regions or interfaces, it considers all strings as being independent variables, as opposed to models. *Model Commands* (page 76) presents commands which have the concepts of models. A; should be used to separate each statement.

This is a sample invocation from DEVSIM

```
% symdiff(expr="subst(dog * cat, dog, bear)")
(bear * cat)
```

10.3.2 Evaluating external math

The ds.register_function() (page 87) is used to evaluate functions declared or defined within SYMDIFF. A Python procedure may then be used taking the same number of arguments. For example:

```
from math import cos
from math import sin
symdiff(expr="declare(sin(x))")
symdiff(expr="define(cos(x), -sin(x))")
symdiff(expr="define(sin(x), cos(x))")
register_function(name="cos", nargs=1)
register_function(name="sin", nargs=1)
```

The cos and sin function may then be used for model evaluation. For improved efficiency, it is possible to create procedures written in C or C++ and load them into Python.

10.3.3 Models

When used withing the model commands discussed in *Model Commands* (page 76), DEVSIM has been extended to recognize model names in the expressions. In this situation, the derivative of a model named, model, with respect to another model, variable, is then model:variable.

During the element assembly process, DEVSIM evaluates all models of an equation together. While the expressions in models and their derivatives are independent, the software uses a caching scheme to ensure that redundant calculations are not performed. It is recommended, however, that users developing their own models investigate creating intermediate models in order to improve their understanding of the equations that they wish to be assembled.

Visualization

11.1 Introduction

DEVSIM is able to create files for visualization tools. Information about acquiring these tools are presented in *External Software Tools* (page 53).

11.2 Using Tecplot

The ds.write_devices() (page 76) is used to create an ASCII file suitable for use in Tecplot. Edge quantities are interpolated onto the node positions in the resulting structure. Element edge quantities are interpolated onto the centers of each triangle or tetrahedron in the mesh.

```
write_devices(file="mos_2d_dd.dat", type="tecplot")
```

11.3 Using Postmini

The ds.write_devices() (page 76) is used to create an ASCII file suitable for use in Postmini. Edge and element edge quantities are interpolated onto the node positions in the resulting structure.

```
write_devices(file="mos_2d_dd.flps", type="floops")
```

11.4 Using Paraview

The ds.write_devices() (page 76) is used to create an ASCII file suitable for use in ParaView. Edge quantities are interpolated onto the node positions in the resulting structure. Element edge quantities are interpolated onto the centers of each triangle or tetrahedron in the mesh.

```
write_devices(file="mos_2d_dd", type="vtk")
```

One vtu file per device region will be created, as well as a vtm file which may be used to load all of the device regions into ParaView.

11.5 Using Vislt

VisIt supports reading the Tecplot and ParaView formats. When using the vtk option on the ds. write_devices() (page 76), a file with a visit filename extension is created to load the files created for ParaView.

11.6 DEVSIM

DEVSIM has several commands for getting information on the mesh. Those related to post processing are described in *Model Commands* (page 76) and *Geometry Commands* (page 64).

See *Loading and saving results* (page 36) for information about loading and saving mesh information to a file.

Installation

12.1 Availability

Information about the open source version of DEVSIM is available from https://www.devsim.org. This site contains up-to-date information about where to obtain compiled and source code versions of this software. It also contains information about how to get support and participate in the development of this project.

12.2 Supported platforms

DEVSIM is compiled and tested on the platforms in Table 12.1. If you require a version on a different software platform, please contact us.

Platform	Bits	OS Version
Microsoft Windows	64	Microsoft Windows 7
Linux	64	Ubuntu 14.04 (LTS)
		lubuntusenial
		Red Hat Enterprise Linux 6 (Centos 6 compatible)
Apple Mac OS X	64	Mac OS X 10.10 (Yosemite)

Table 12.1: Current platforms for DEVSIM.

12.3 Binary availability

Compiled packages for the the platforms in Table 12.1 are currently available from |devsimgithubreleas|. The prerequisites on each platform are the default Python and Tol packages for your operating system. Information about required packages for Microsoft Windows 7 are in the file windows.txt.

12.4 Source code availability

DEVSIM is also available in source code form from https://github.com/devsim/devsim.

12.5 Directory Structure

A DEVSIM directory is created with the following sub directories listed in Table 12.2.

Table 12.2: Directory structure for DEVSIM.

bin	contains the devsim binary
doc	contains product documentation
examples	contains example scripts
python_packages	contains runtime libraries
testing	contains additional examples used for testing

12.6 Running DEVSIM

See *User Interface* (page 39) for instructions on how to invoke DEVSIM.

Additional Information

13.1 DEVSIM License

Individual files are covered by the license terms contained in the comments at the top of the file. Contributions to this project are subject to the license terms of their authors. In general, DEVSIM is covered by the Apache License, Version 2.0 [ApacheSoftwareFoundation] (page 111). Please see the NOTICE and LICENSE file for more information.

13.2 SYMDIFF

SYMDIFF is available from http://www.symdiff.org and is covered by the terms of the Apache License, Version 2.0 [ApacheSoftwareFoundation] (page 111).

13.3 External Software Tools

13.3.1 **Genius**

Genius is available in commercial and open source versions from http://www.cogenda.com.

13.3.2 Gmsh

Gmsh [GR09] (page 111) is available from http://gmsh.info.

13.3.3 Paraview

ParaView is an open source visualization tool available at http://www.paraview.org.

13.3.4 Tecplot

Tecplot is a commercial visualization tool available from http://www.tecplot.com.

13.3.5 Vislt

VisIt is an open source visualization tool available from https://wci.llnl.gov/codes/visit/.

13.4 Library Availablilty

The following tools are used to build DEVSIM.

13.4.1 BLAS and LAPACK

These are the basic linear algebra routines used directly by DEVSIM and by SuperLU. Reference versions are available from http://www.netlib.org. There are optimized versions available from other vendors.

13.4.2 CGNS

CGNS (CFD Generalized Notation System) is an open source library, which implements the storage format used to read Genius Device Simulator meshes. It is available from http://www.cgns.org.

13.4.3 Python

A Python distribution is required for using DEVSIM and is distributed with many operating system. Additional information is available at https://www.python.org. It should be stressed that binary packages must be compatible with the Python distribution used by DEVSIM.

13.4.4 SQlite3

SQLite3 is an open source database engine used for the material database and is available from https://www.sqlite.org.

13.4.5 **SuperLU**

SuperLU [DEG+99] (page 111) is used within DEVSIM and is available from http://crd-legacy.lbl. gov/~xiaoye/SuperLU:

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13.4.6 Tcl

Tcl is the original parser for DEVSIM and is superseded by Python. It is still used for some of the tests. Tcl is available from http://www.tcl.tk.

13.4.7 zlib

zlib is an open source compression library available from https://zlib.net.

Command Reference

14.1 Circuit Commands

```
Commands are for adding circuit elements to the simulation.
ds.add_circuit_node (name, value, variable_update)
      Adds a circuit node for use in circuit or multi-device simulation
           Parameters name: str
                   Name of the circuit node being created
               value: Float, optional
                   initial value (default 0.0)
               variable_update : {'default', 'log_damp', 'positive'}
                   update type for circuit variable
ds.circuit_alter(name, param, value)
     Alter the value of a circuit element parameter
           Parameters name: str
                   Name of the circuit node being created
               param : str, optional
                   parameter being modified (default 'value')
               value: Float
                   value for the parameter
ds.circuit_element(name, value, n1, n2, acreal, acimag)
     Adds a circuit element external to the devices
```

Parameters name: str

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```
Name of the circuit element being created. A prefix of 'V' is for voltage source, 'I' for current source, 'R' for resistor, 'L' for inductor, and 'C' for capacitor.
```

value: Float, optional

value for the default parameter of the circuit element (default 0.0)

n1: str

circuit node

n2: str

circuit node

acreal: Float, optional

real part of AC source for voltage (default 0.0)

acimag: Float, optional

imag part of AC source for voltage (default 0.0)

ds.circuit node alias (node, alias)

Create an alias for a circuit node

Parameters node: str

circuit node being aliased

alias: str

alias for the circuit node

ds.get_circuit_equation_number(node)

Returns the row number correspond to circuit node in a region. Values are only valid when during the course of a solve.

Parameters node: str

circuit node

ds.get circuit node list()

Gets the list of the nodes in the circuit.

ds.get_circuit_node_value(solution, node)

Gets the value of a circuit node for a given solution type.

Parameters solution: str, optional

name of the solution. 'dcop' is the name for the DC solution (default 'dcop')

node: str

circuit node of interest

ds.get_circuit_solution_list()

Gets the list of available circuit solutions.

ds.set_circuit_node_value(solution, node, value)

Sets the value of a circuit node for a given solution type.

Parameters solution: str, optional

name of the solution. 'dcop' is the name for the DC solution (default 'dcop')

node: str

circuit node of interest

value: Float, optional

new value (default 0.0)

14.2 Equation Commands

Commands for manipulating equations on contacts, interface, and regions

```
ds.contact_equation(device, contact, name, variable_name, circuit_node, edge_charge_model, edge_current_model, edge_model, element_charge_model, element_current_model, element_model, node_charge_model, node_current_model, node_model)
```

Create a contact equation on a device

Parameters device: str

The selected device

contact: str

Contact on which to apply this command

name: str

Name of the contact equation being created

variable_name: str, optional

The variable name is used to determine the bulk equation we are replacing at this contact

circuit node: str, optional

Name of the circuit we integrate the flux into

edge_charge_model : str, optional

Name of the edge model used to determine the charge at this contact

edge_current_model : str, optional

Name of the edge model used to determine the current flowing out of this contact

edge_model : str, optional

Name of the edge model being integrated at each edge at this contact

element_charge_model : str, optional

Name of the element edge model used to determine the charge at this contact

element_current_model : str, optional

Name of the element edge model used to determine the current flowing out of this contact

element_model: str, optional

Name of the element edge model being integrated at each edge at this contact

node_charge_model: str, optional

Name of the node model used to determine the charge at this contact

node_current_model : str, optional

Name of the node model used to determine the current flowing out of this contact

node_model : str, optional

Name of the node_model being integrated at each node at this contact

ds.custom_equation(name, procedure)

Custom equation assembly. See *Custom matrix assembly* (page 26) for a description of how the function should be structured.

Parameters name: str

Name of the custom equation being created

procedure: str

The procedure to be called

ds.delete_contact_equation(device, contact, name)

This command deletes an equation from a contact.

Parameters device: str

The selected device

contact : str

Contact on which to apply this command

name: str

Name of the contact equation being deleted

ds.delete_equation(device, region, name)

This command deletes an equation from a region.

Parameters device: str

The selected device

region: str

The selected region

name: str

Name of the equation being deleted

ds.delete_interface_equation(device, interface, name)

This command deletes an equation from an interface.

Parameters device: str

The selected device

interface: str

Interface on which to apply this command

name: str

Name of the interface equation being deleted

ds.equation(device, region, name, variable_name, node_model, edge_model, edge_volume_model, time_node_model, element_model, volume_model, variable update)

Specify an equation to solve on a device

Parameters device: str

The selected device

region: str

The selected region

name: str

Name of the equation being created

variable_name : str

Name of the node_solution being solved

node_model : str, optional

Name of the node_model being integrated at each node in the device volume

edge_model : str, optional

Name of the edge model being integrated over each edge in the device volume

edge_volume_model: str, optional

Name of the edge model being integrated over the volume of each edge in the device volume

time_node_model: str, optional

Name of the time dependent node_model being integrated at each node in the device volume

element_model: str, optional

Name of the element_model being integrated over each edge in the device volume

volume_model : str, optional

Name of the element_model being integrated over the volume of each edge in the device volume

variable_update: str, optional

update type for circuit variable (default 'default')

Notes

The integration variables can be changed in 2D for cylindrical coordinate systems by setting the appropriate parameters as described in *Cylindrical Coordinate Systems* (page 27).

In order to set the node volumes for integration of the <code>edge_volume_model</code>, it is possible to do something like this:

ds.get_contact_equation_command(device, contact, name)

This command gets the options used when creating this contact equation.

Parameters device: str

The selected device

contact : str

Contact on which to apply this command

name: str

Name of the contact equation being command options returned

ds.get_contact_equation_list(device, contact)

This command gets a list of equations on the specified contact.

Parameters device: str

The selected device

contact: str

Contact on which to apply this command

ds.get_equation_command(device, region, name)

This command gets the options used when creating this equation.

Parameters device: str

The selected device

region : str

The selected region

name: str

Name of the equation being command options returned

ds.get_equation_list(device, region)

This command gets a list of equations on the specified region.

Parameters device: str

The selected device

region: str

The selected region

ds.get_equation_numbers(device, region, equation, variable)

Returns a list of the equation numbers corresponding to each node in a region. Values are only valid when during the course of a solve.

Parameters device: str

The selected device

region: str

The selected region

equation: str, optional

Name of the equation

variable: str, optional

Name of the variable

ds.get_interface_equation_command(device, interface, name)

This command gets the options used when creating this interface equation.

Parameters device: str

The selected device

interface: str

Interface on which to apply this command

name: str

Name of the interface equation being command options returned

ds.get_interface_equation_list(device, interface)

This command gets a list of equations on the specified interface.

Parameters device: str

The selected device

interface: str

Interface on which to apply this command

ds.interface_equation(device, interface, name, variable_name, interface_model, type)

Command to specify an equation at an interface

Parameters device: str

The selected device

interface: str

Interface on which to apply this command

name: str

Name of the interface equation being created

variable_name : str

The variable name is used to determine the bulk equation we are coupling this interface to

interface_model : str

When specified, the bulk equations on both sides of the interface are integrated together. This model is then used to specify how nodal quantities on both sides of the interface are balanced

type : str

Specifies the type of boundary condition

14.3 Geometry Commands

Commands for getting information about the device structure.

ds.get_contact_list(device)

Gets a list of contacts on a device.

Parameters device: str

The selected device

ds.get_device_list()

Gets a list of devices on the simulation.

ds.get_interface_list(device)

Gets a list of interfaces on a device.

Parameters device: str

The selected device

ds.get_region_list (device, contact, interface)

Gets a list of regions on a device, contact, or interface.

Parameters device: str

The selected device

contact : str, optional

If specified, gets the name of the region belonging to this contact on the device

interface: str, optional

If specified, gets the name of the regions belonging to this interface on the device

14.4 Material Commands

Commands for manipulating parameters and material properties

ds.add_db_entry (material, parameter, value, unit, description)

Adds an entry to the database

Parameters material: str

Material name requested. global refers to all regions whose material does not have the parameter name specified

parameter: str

Parameter name

value : str

Value assigned for the parameter

unit: str

String describing the units for this parameter name

description: str

Description of the parameter for this material type.

Notes

The ds.save_db() (page 67) command is used to commit these added entries permanently to the database.

ds.close_db()

Closes the database so that its entries are no longer available

ds.create_db(filename)

Create a database to store material properties

Parameters filename: str

filename to create for the db

ds.get_db_entry(material, parameter)

This command returns a list containing the value, unit, and description for the requested material db entry

Parameters material: str

Material name

parameter: str

Parameter name

ds.get_dimension(device)

Get the dimension of the device

Parameters device: str, optional

The selected device

ds.get_material(device, region)

Returns the material for the specified region

Parameters device: str, optional

The selected device

region: str, optional

The selected region

ds.get_parameter(device, region, name)

Get a parameter on a region, device, or globally.

Parameters device: str, optional

The selected device

region: str, optional

The selected region

name: str

Name of the parameter name being retrieved

Notes

Note that the device and region options are optional. If the region is not specified, the parameter is retrieved for the entire device. If the device is not specified, the parameter is retrieved for all devices. If the parameter is not found on the region, it is retrieved on the device. If it is not found on the device, it is retrieved over all devices.

ds.get_parameter_list(device, region)

Get list of parameter names on region, device, or globally

Parameters device: str, optional

The selected device

region: str, optional

The selected region

Notes

Note that the device and region options are optional. If the region is not specified, the parameter is retrieved for the entire device. If the device is not specified, the parameter is retrieved for all devices. Unlike the ds.getParameter(), parameter names on the device are not retrieved if they do not exist on the region. Similarly, the parameter names over all devices are not retrieved if they do not exist on the device.

ds.open_db (filename, permissions)

Open a database storing material properties

Parameters filename: str

filename to create for the db

permissions: str, optional

permissions on the db (default 'readonly')

ds.save_db()

Saves any new or modified db entries to the database file

ds.set_material(device, region, material)

Sets the new material for a region

Parameters device: str, optional

The selected device

region: str, optional

The selected region

material: str

New material name

ds.set_parameter(device, region, name, value)

Set a parameter on region, device, or globally

Parameters device: str, optional

The selected device

region: str, optional

The selected region

name: str

Name of the parameter name being retrieved

value: any

value to set for the parameter

Notes

Note that the device and region options are optional. If the region is not specified, the parameter is set for the entire device. If the device is not specified, the parameter is set for all devices.

14.5 Meshing Commands

```
Commands for reading and writing meshes
```

```
ds.add_1d_contact (material, mesh, name, tag)
```

Add a contact to a 1D mesh

Parameters material: str

material for the contact being created

mesh: str

Mesh to add the contact to

name: str

Name for the contact being created

tag: str

Text label for the position to add the contact

ds.add_1d_interface(mesh, tag, name)

Add an interface to a 1D mesh

Parameters mesh: str

Mesh to add the interface to

tag: str

Text label for the position to add the interface

name: str

iaine . su

Name for the interface being created

ds.add_1d_mesh_line(mesh, tag, pos, ns, ps)

Add a mesh line to a 1D mesh

Parameters mesh: str

Mesh to add the line to

tag: str, optional

Text label for the position

pos: str

Position for the mesh point

```
ns: Float, optional
                    Spacing from this point in the negative direction (default ps value)
               ps: Float
                    Spacing from this point in the positive direction
ds.add_1d_region (mesh, tag1, tag2, region, material)
      Add a region to a 1D mesh
           Parameters mesh: str
                    Mesh to add the line to
               tag1: str
                    Text label for the position bounding the region being added
               tag2: str
                    Text label for the position bounding the region being added
               region: str
                    Name for the region being created
               material: str
                    Material for the region being created
ds.add_2d_contact (name, material, mesh, region, xl, xh, yl, yh, bloat)
      Add an interface to a 2D mesh
           Parameters name: str
                    Name for the contact being created
               material: str
                    material for the contact being created
               mesh: str
                    Mesh to add the contact to
               region: str
                    Name of the region included in the contact
               xl: Float, optional
                    x position for corner of bounding box (default -MAXDOUBLE)
               xh: Float, optional
                    x position for corner of bounding box (default +MAXDOUBLE)
               yl: Float, optional
                    y position for corner of bounding box (default -MAXDOUBLE)
               yh: Float, optional
```

```
bloat: Float, optional
                   Extend bounding box by this amount when search for mesh to include in
                   region (default 1e-10)
ds.add_2d_interface (mesh, name, region0, region1, xl, xh, yl, yh, bloat)
      Add an interface to a 2D mesh
           Parameters mesh: str
                   Mesh to add the interface to
               name: str
                   Name for the interface being created
               region0: str
                   Name of the region included in the interface
               region1 : str
                   Name of the region included in the interface
               xl: Float, optional
                   x position for corner of bounding box (default -MAXDOUBLE)
               xh: Float, optional
                   x position for corner of bounding box (default +MAXDOUBLE)
               yl: Float, optional
                   y position for corner of bounding box (default -MAXDOUBLE)
               yh: Float, optional
                   y position for corner of bounding box (default +MAXDOUBLE)
               bloat: Float, optional
                   Extend bounding box by this amount when search for mesh to include in
                   region (default 1e-10)
ds.add_2d_mesh_line(mesh, pos, ns, ps)
      Add a mesh line to a 2D mesh
           Parameters mesh: str
                   Mesh to add the line to
               pos: str
                   Position for the mesh point
               ns: Float
                   Spacing from this point in the negative direction
```

y position for corner of bounding box (default +MAXDOUBLE)

```
ps: Float
                   Spacing from this point in the positive direction
ds.add 2d region (mesh, region, material, xl, xh, yl, yh, bloat)
     Add a region to a 2D mesh
           Parameters mesh: str
                   Mesh to add the region to
               region: str
                   Name for the region being created
               material: str
                   Material for the region being created
               xl: Float, optional
                   x position for corner of bounding box (default -MAXDOUBLE)
               xh: Float, optional
                   x position for corner of bounding box (default +MAXDOUBLE)
               yl: Float, optional
                   y position for corner of bounding box (default -MAXDOUBLE)
               yh: Float, optional
                   y position for corner of bounding box (default +MAXDOUBLE)
               bloat: Float, optional
                   Extend bounding box by this amount when search for mesh to include in
                   region (default 1e-10)
ds.add_genius_contact(genius_name, material, mesh, name, region)
     Create a contact for an imported Genius mesh
           Parameters genius_name : str
                   boundary condition name in the Genius CGNS file
               material: str
                   material for the contact being created
               mesh: str
                   name of the mesh being generated
               name: str
                   name of the contact begin created
```

region: str

region that the contact is attached to

```
ds.add_genius_interface(genius_name, mesh, name, region0, region1)
     Create an interface for an imported Genius mesh
          Parameters genius_name : str
                   boundary condition name in the Genius CGNS file
               mesh: str
                   name of the mesh being generated
               name: str
                   name of the interface begin created
               region0: str
                   first region that the interface is attached to
               region1: str
                   second region that the interface is attached to
ds.add_genius_region(genius_name, mesh, region, material)
     Create a region for an imported Genius mesh
          Parameters genius_name : str
                   region name in the Genius CGNS file
               mesh: str
                   name of the mesh being generated
               region: str
                   name of the region begin created
               material: str
                   material for the region being created
ds.add_gmsh_contact(gmsh_name, material, mesh, name, region)
     Create a mesh to import a Gmsh mesh
          Parameters gmsh_name : str
                   physical group name in the Gmsh file
               material: str
                   material for the contact being created
               mesh: str
                   name of the mesh being generated
               name: str
                   name of the contact begin created
               region: str
```

region that the contact is attached to

ds.add_gmsh_interface(gmsh_name, mesh, name, region0, region1)

Create an interface for an imported Gmsh mesh

Parameters gmsh_name: str

physical group name in the Gmsh file

mesh: str

name of the mesh being generated

name: str

name of the interface begin created

region0 : str

first region that the interface is attached to

region1 : str

second region that the interface is attached to

ds.add_gmsh_region(gmsh_name, mesh, region, material)

Create a region for an imported Gmsh mesh

Parameters gmsh_name : str

physical group name in the Gmsh file

mesh: str

name of the mesh being generated

region : str

name of the region begin created

material: str

material for the region being created

ds.create 1d mesh (mesh)

Create a mesh to create a 1D device

Parameters mesh: str

name of the 1D mesh being created

ds.create_2d_mesh(mesh)

Create a mesh to create a 2D device

Parameters mesh: str

name of the 2D mesh being created

ds.create_contact_from_interface (device, region, interface, material, name)

Creates a contact on a device from an existing interface

Parameters device: str

The selected device

region: str

The selected region

interface: str

Interface on which to apply this command

material: str

material for the contact being created

name: str

name of the contact begin created

ds.create_device(mesh, device)

Create a device from a mesh

Parameters mesh: str

name of the mesh being used to create a device

device: str

name of the device being created

ds.create_genius_mesh (file, mesh)

This command reads in a Genius mesh written in the CGNS format

Parameters file: str

name of the Genius mesh file being read into DEVSIM

mesh: str

name of the mesh being generated

Notes

If successful, this command will return a dictionary containing information about the regions and boundaries in the mesh. Please see the example in *Genius* (page 34) for an example of how this information can be used for adding contacts and interfaces to the structure being created.

If the CGNS file was created with HDF as the underlying storage format, it may be necessary to convert it to ADF using the hdf2adf command before reading it into DEVSIM. This command is available as part of the CGNS library when it is compiled with HDF support. Please *CGNS* (page 54) for availablility. }

ds.create_gmsh_mesh (mesh, file, coordinates, elements, physical_names)

Create a mesh to import a Gmsh mesh

Parameters mesh: str

name of the mesh being generated

file: str, optional

name of the Gmsh mesh file being read into DEVSIM

coordinates: list, optional

List of coordinate positions on mesh.

elements: list, optional

List of elements on the mesh.

physical_names: list, optional

List of names for each contact, interface, and region on mesh.

Notes

This file will import a Gmsh format mesh from a file. Alternatively, the mesh structure may be passed in as as arguments:

coordinates is a float list of positions in the mesh. Each coordinate adds an x, y, and z position so that the coordinate list length is 3 times the number of coordinates.

physical_names is a list of contact, interface, and region names. It is referenced by index by the elements list.

elements is a list of elements. Each element adds

- •Element Type (float)
 - -0 node
 - -1 edge
 - -2 triangle
 - -3 tetrahedron
- Physical Index
 - -This indexes into the physical_names list.
- Nodes
 - -Each node of the element indexes into the coordinates list.

$ds.finalize_mesh(mesh)$

Finalize a mesh so no additional mesh specifications can be added and devices can be created.

Parameters mesh: str

Mesh to finalize

ds.load_devices(file)

Load devices from a DEVSIM file

Parameters file: str

```
name of the file to load the meshes from
ds.write_devices(file, device, type)
      Write a device to a file for visualization or restart
           Parameters file: str
                   name of the file to write the meshes to
               device: str, optional
                   name of the device to write
               type: {'devsim', 'devsim_data', 'floops', 'tecplot', 'vtk'}
                   format to use
14.6 Model Commands
Commands for defining and evaluating models
ds.contact_edge_model (device, contact, name, equation, display_type)
      Create an edge model evaluated at a contact
           Parameters device: str
                   The selected device
               contact: str
                   Contact on which to apply this command
               name: str
                   Name of the contact edge model being created
               equation: str
                   Equation used to describe the contact edge model being created
               display_type : {'vector', 'nodisplay', 'scalar'}
                   Option for output display in graphical viewer
ds.contact_node_model(device, contact, name, equation, display_type)
     Create an node model evaluated at a contact
           Parameters device: str
                   The selected device
               contact: str
                   Contact on which to apply this command
               name: str
```

Name of the contact node model being created

```
equation : str
```

Equation used to describe the contact node model being created

```
display_type : {'scalar', 'nodisplay'}
```

Option for output display in graphical viewer

ds.cylindrical_edge_couple(device, region)

This command creates the EdgeCouple model for 2D cylindrical simulation

Parameters device: str

The selected device

region: str

The selected region

Notes

This model is only available in 2D. The created variables are

- •ElementCylindricalEdgeCouple (Element Edge Model)
- •CylindricalEdgeCouple (Edge Model)

The ds.set_parameter() (page 67) must be used to set

- \bullet raxis_variable, the variable (x or y) which is the radial axis variable in the cylindrical coordinate system
- •raxis_zero, the location of the z axis for the radial axis variable

ds.cylindrical_node_volume(device, region)

This command creates the NodeVolume model for 2D cylindrical simulation

Parameters device : str

The selected device

region: str

The selected region

Notes

This model is only available in 2D. The created variables are

- •ElementCylindricalNodeVolume@en0 (Element Edge Model)
- •ElementCylindricalNodeVolume@en1 (Element Edge Model)
- •CylindricalEdgeNodeVolume@n0 (Edge Model)
- •CylindricalEdgeNodeVolume@n1 (Edge Model)

•CylindricalNodeVolume (Node Model)

The ElementCylindricalNodeVolume@en0 and ElementCylindricalNodeVolume@en1 represent the node volume at each end of the element edge.

The ds.set_parameter() (page 67) must be used to set

- •raxis_variable, the variable (x or y) which is the radial axis variable in the cylindrical coordinate system
- •raxis_zero, the location of the z axis for the radial axis variable

ds.cylindrical_surface_area(device, region)

This command creates the SurfaceArea model for 2D cylindrical simulation

Parameters device: str

The selected device

region : str

The selected region

Notes

This model is only available in 2D. The created variables are

•CylindricalSurfaceArea (Node Model)

and is the cylindrical surface area along each contact and interface node in the device region.

The ds.set_parameter() (page 67) must be used to set

- \cdot raxis_variable, the variable (x or y) which is the radial axis variable in the cylindrical coordinate system
- •raxis_zero, the location of the z axis for the radial axis variable

ds.debug_triangle_models(device, region)

Debugging command used in the development of DEVSIM and used in regressions.

Parameters device: str

The selected device

region: str

The selected region

ds.delete_edge_model(device, region, name)

Deletes an edge model from a region

Parameters device: str

The selected device

region: str

The selected region

```
name: str
```

Name of the edge model being deleted

ds.delete_element_model(device, region, name)

Deletes a element model from a region

Parameters device: str

The selected device

region: str

The selected region

name: str

Name of the node model being deleted

ds.delete_interface_model(device, interface, name)

Deletes an interface model from an interface

Parameters device: str

The selected device

interface: str

Interface on which to apply this command

name: str

Name of the interface model being deleted

ds.delete_node_model(device, region, name)

Deletes a node model from a region

Parameters device: str

The selected device

region: str

The selected region

name: str

Name of the node model being deleted

ds.edge_average_model (device, region, node_model, edge_model, derivative, average_type)

Creates an edge model based on the node model values

Parameters device: str

The selected device

region : str

The selected region

node_model: str

The node model from which we are creating the edge model. If derivative is specified, the edge model is created from nodeModel:derivativeModel

edge_model: str

The edge model name being created. If derivative is specified, the edge models created are edgeModel:derivativeModel@n0 edgeModel:derivativeModel@n1, which are the derivatives with respect to the derivative model on each side of the edge

derivative: str, optional

The node model of the variable for which the derivative is being taken. The node model nodeModel: derivativeModel is used to create the resulting edge models.

```
average_type : str, optional
```

The node models on both sides of the edge are averaged together to create one of the following types of averages. (default 'arithmetic')

Notes

For a node model, creates 2 edge models referring to the node model value at both ends of the edge. For example, to calculate electric field:

```
ds.edge_average_model(device=device, region=region, node_model="Potential", edge_model="ElecticField", average_type="negative_gradient")
```

and the derivatives ElectricField:Potential@n0 and ElectricField:Potential@n1 are then created from

```
ds.edge_average_model(device=device, region=region, node_model="Potential", edge_model="ElecticField", average_type="negative_gradient", derivative="Potential")
```

ds.edge_from_node_model (device, region, node_model)

For a node model, creates an 2 edge models referring to the node model value at both ends of the edge.

Parameters device: str

The selected device

region: str

The selected region

node_model: str

The node model from which we are creating the edge model

Notes

```
For example, to calculate electric field:

ds.edge_from_node_model(device=device, region=region, node_model="Potential")

ds.edge_model (device, region, name, equation, display_type)

Creates an edge model based on an equation

Parameters device: str

The selected device

region: str

The selected region

name: str

Name of the edge model being created

equation: str

Equation used to describe the edge model being created

display_type: str, optional

Option for output display in graphical viewer (default 'scalar')
```

Notes

The vector option uses an averaging scheme for the edge values projected in the direction of each edge. For a given model, model, the generated components in the visualization files is:

```
model_x_onNodemodel_y_onNodemodel_z_onNode (3D)
```

This averaging scheme does not produce accurate results, and it is recommended to use the <code>ds.element_from_edge_model()</code> (page 81) to create components better suited for visualization. See <code>Visualization</code> (page 49) for more information about creating data files for external visualization programs.

ds.element_from_edge_model(device, region, edge_model, derivative)

Creates element edge models from an edge model

```
Parameters device : str

The selected device
region : str

The selected region
edge_model : str
```

The edge model from which we are creating the element model

derivative: str, optional

The variable we are taking with respect to edge_model

Notes

For an edge model emodel, creates an element models referring to the directional components on each edge of the element:

- $-emodel_x$
- •emodel_y

If the derivative variable option is specified, the <code>emodel@n0</code> and <code>emodel@n1</code> are used to create:

- •emodel_x:variable@en0
- •emodel_y:variable@en0
- •emodel_x:variable@en1
- •emodel_y:variable@en1
- •emodel_x:variable@en2
- •emodel_y:variable@en2

in 2D for each node on a triangular element. and

- •emodel_x:variable@en0
- •emodel_y:variable@en0
- •emodel z:variable@en0
- •emodel_x:variable@en1
- •emodel_y:variable@en1
- •emodel_z:variable@en1
- •emodel_x:variable@en2
- •emodel_y:variable@en2
- •emodel_z:variable@en2
- •emodel_x:variable@en3
- •emodel_y:variable@en3
- •emodel z:variable@en3

in 3D for each node on a tetrahedral element.

The suffix en0 refers to the first node on the edge of the element and en1 refers to the second node. en2 and en3 specifies the derivatives with respect the variable at the nodes opposite the edges on the element being considered.

ds.element_from_node_model(device, region, node_model)

Creates element edge models from a node model

Parameters device: str

The selected device

region: str

The selected region

node_model: str

The node model from which we are creating the edge model

Notes

This command creates an element edge model from a node model so that each corner of the element is represented. A node model, nmodel, would be be accessible as

- •nmodel@en0
- •nmodel@en1
- •nmodel@en2
- •nmodel@en3(3D)

where en0, and en1 refers to the nodes on the element's edge. In 2D, en2 refers to the node on the triangle node opposite the edge. In 3D, en2 and en3 refers to the nodes on the nodes off the element edge on the tetrahedral element.

ds.element_model(device, region, name, equation, display_type)

Create a model evaluated on element edges.

Parameters device: str

The selected device

region: str

The selected region

name: str

Name of the element edge model being created

equation: str

Equation used to describe the element edge model being created

display_type: str, optional

Option for output display in graphical viewer (default 'scalar')

ds.get_edge_model_list(device, region)

Returns a list of the edge models on the device region

Parameters device: str

The selected device

region: str

The selected region

ds.get_edge_model_values(device, region, name)

Get the edge model values calculated at each edge.

Parameters device: str

The selected device

region: str

The selected region

name: str

Name of the edge model values being returned as a list

ds.get_element_model_list (device, region)

Returns a list of the element edge models on the device region

Parameters device: str

The selected device

region: str

The selected region

ds.get_element_model_values(device, region, name)

Get element model values at each element edge

Parameters device: str

The selected device

region: str

The selected region

name: str

Name of the element edge model values being returned as a list

ds.get_interface_model_list(device, interface)

Returns a list of the interface models on the interface

Parameters device: str

The selected device

interface: str

Interface on which to apply this command

ds.get_interface_model_values(device, interface, name)

Gets interface model values evaluated at each interface node.

Parameters device: str

The selected device

interface: str

Interface on which to apply this command

name: str

Name of the interface model values being returned as a list

ds.get_node_model_list(device, region)

Returns a list of the node models on the device region

Parameters device: str

The selected device

region: str

The selected region

ds.get_node_model_values(device, region, name)

Get node model values evaluated at each node in a region.

Parameters device : str

The selected device

region: str

The selected region

name: str

Name of the node model values being returned as a list

ds.interface_model(device, interface, equation)

Create an interface model from an equation.

Parameters device: str

The selected device

interface: str

Interface on which to apply this command

equation : str

Equation used to describe the interface node model being created

ds.interface_normal_model(device, region, interface)

Creates edge models whose components are based on direction and distance to an interface

Parameters device: str

The selected device

```
region: str
                   The selected region
               interface: str
                   Interface on which to apply this command
     Notes
     This model creates the following edge models:
          •iname distance
          •iname_normal_x (2D and 3D)
          •iname_normal_y (2D and 3D)
          •iname_normal_z (3D only)
     where iname is the name of the interface. The normals are of the closest node on the interface. The
     sign is toward the interface.
ds.node_model(device, region, name, equation, display_type)
     Create a node model from an equation.
          Parameters device: str
                   The selected device
               region: str
                   The selected region
               name: str
                   Name of the node model being created
               equation: str
                   Equation used to describe the node model being created
               display_type: str, optional
                   Option for output display in graphical viewer (default 'scalar')
ds.node_solution(device, region, name)
     Create node model whose values are set.
          Parameters device: str
                   The selected device
               region: str
```

Name of the solution being created

The selected region

name: str

ds.print_edge_values(device, region, name)

Print edge values for debugging.

Parameters device: str

The selected device

region: str

The selected region

name: str

Name of the edge model values being printed to the screen

ds.print_element_values (device, region, name)

Print element values for debugging.

Parameters device: str

The selected device

region: str

The selected region

name: str

Name of the element edge model values being printed to the screen

ds.print_node_values(device, region, name)

Print node values for debugging.

Parameters device: str

The selected device

region: str

The selected region

name: str

Name of the node model values being printed to the screen

ds.register_function(name, nargs)

This command is used to register a new Python procedure for evaluation by SYMDIFF.

Parameters name: str

Name of the function

nargs: str

Number of arguments to the function

ds.set_node_value (device, region, name, index, value)

A uniform value is used if index is not specified. Note that equation based node models will lose this value if their equation is recalculated.

Parameters device: str

The selected device

region: str

The selected region

name: str

Name of the node model being whose value is being set

index: int

Index of node being set

value: Float

Value of node being set

ds.set_node_values (device, region, name, init_from, values)

Set node model values from another node model, or a list of values.

Parameters device: str

The selected device

region: str

The selected region

name: str

Name of the node model being initialized

init_from : str, optional

Node model we are using to initialize the node solution

values: list, optional

List of values for each node in the region.

ds.symdiff(expr)

This command returns an expression. All strings are treated as independent variables. It is primarily used for defining new functions to the parser.

Parameters expr: str

Expression to send to SYMDIFF

ds.vector_element_model (device, region, element_model)

Create vector components from an element edge model

Parameters device: str

The selected device

region : str

The selected region

element_model: str

The element model for which we are calculating the vector components

Notes

This command creates element edge models from an element model which represent the vector components on the element edge. An element model, emodel, would then have

```
emodel_xemodel_yemodel_z (3D only)
```

The primary use of these components are for visualization.

```
ds.vector_gradient (device, region, node_model, calc_type)
Creates the vector gradient for noise analysis
```

```
Parameters device : str

The selected device
```

region: str

The selected region

node_model : str

The node model from which we are creating the edge model

calc_type : str, optional

The node model from which we are creating the edge model (default 'default')

Notes

Used for noise analysis. The avoidzero option is important for noise analysis, since a node model value of zero is not physical for some contact and interface boundary conditions. For a given node model, model, a node model is created in each direction:

```
model_gradx (1D)model_grady (2D and 3D)model_gradz (3D)
```

It is important not to use these models for simulation, since DEVSIM, does not have a way of evaluating the derivatives of these models. The models can be used for integrating the impedance field, and other postprocessing. The <code>ds.element_from_edge_model()</code> (page 81) command can be used to create gradients for use in a simulation.

14.7 Solver Commands

```
Commands for simulation
ds.get_contact_charge (device, contact, equation)
      Get charge at the contact
           Parameters device: str
                    The selected device
               contact: str
                    Contact on which to apply this command
               equation: str
                    Name of the contact equation from which we are retrieving the charge
ds.get_contact_current (device, contact, equation)
      Get current at the contact
           Parameters device: str
                    The selected device
               contact: str
                    Contact on which to apply this command
               equation : str
                    Name of the contact equation from which we are retrieving the current
ds.solve(type, solver_type, absolute_error, relative_error, charge_error, gamma, tdelta, maxi-
             mum_iterations, frequency, output_node, info)
      Call the solver. A small-signal AC source is set with the circuit voltage source.
           Parameters type: {'dc', 'ac', 'noise', 'transient_dc', 'transient_bdf1', 'transient_bdf2',
                'transient_tr' } required
                    type of solve being performed
               solver_type : {'direct', 'iterative'} required
                    Linear solver type
               absolute error: Float, optional
                    Required update norm in the solve (default 0.0)
               relative_error: Float, optional
                    Required relative update in the solve (default 0.0)
               charge error: Float, optional
                    Relative error between projected and solved charge during transient simula-
```

tion (default 0.0)

gamma: Float, optional

Scaling factor for transient time step (default 1.0)

tdelta: Float, optional

time step (default 0.0)

maximum_iterations: int, optional

Maximum number of iterations in the DC solve (default 20)

frequency: Float, optional

Frequency for small-signal AC simulation (default 0.0)

output_node : str, optional

Output circuit node for noise simulation

info: bool, optional

Solve command return convergence information (default False)

Chapter 15

Example Overview

In the following chapters, examples are presented for the use of DEVSIM to solve some simulation problems. Examples are also located in the DEVSIM distribution and their location is mentioned in *Directory structure for DEVSIM*. (page 52).

The following example directories are contained in the distribution.

15.1 capacitance

These are 1D and 2D capacitor simulations, using the internal mesher. A description of these examples is presented in *Capacitor* (page 95).

15.2 diode

This is a collection of 1D, 2D, and 3D diode structures using the internal mesher, as well as Gmsh. These examples are discussed in *Diode* (page 105).

15.3 bioapp1

This is a biosensor application.

15.4 genius

This directory has examples importing meshes from Genius Device Simulator.

15.5 vector_potential

This is a 2d magnetic field simulation solving for the magnetic potential. The simulation script is vector_potential/twowire.py A simulation result for two wires conducting current is shown in Fig. 15.1.

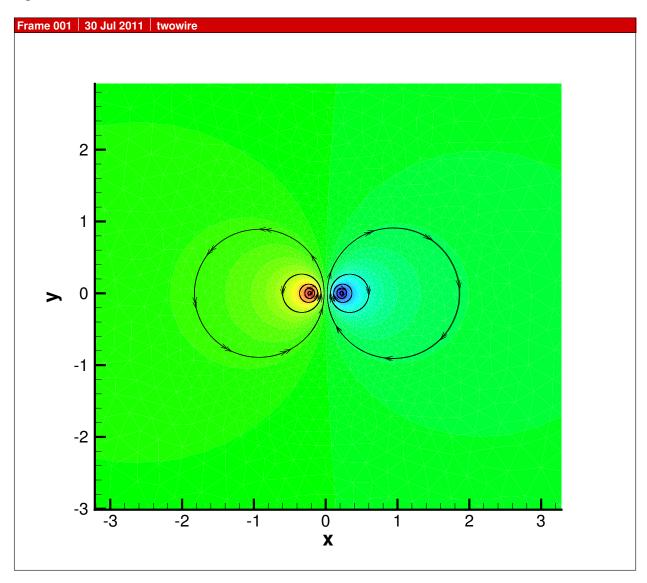


Fig. 15.1: Simulation result for solving for the magnetic potential and field. The coloring is by the Z component of the magnetic potential, and the stream traces are for components of magnetic field.

15.6 mobility

This is an advanced example using electric field dependendent mobility models.

Chapter 16

Capacitor

16.1 Overview

In this chapter, we present a capacitance simulations. The purpose is to demonstrate the use of DEVSIM with a rather simple example. The first example in *1D Capacitor* (page 95) is called capld.py and is located in the examples/capacitance directory distributed with DEVSIM. In this example, we have manually taken the derivative expressions. In other examples, we will show use of SYMDIFF to create the derivatives in an automatic fashion. The second example is in *2D Capacitor* (page 99).

16.2 1D Capacitor

16.2.1 Equations

In this example, we are solving Poisson's equation. In differential operator form, the equation to be solved over the structure is:

$$\epsilon \nabla^2 \psi = 0$$

and the contact boundary equations are

$$\psi_i - V_c = 0$$

where ψ_i is the potential at the contact node and V_c is the applied voltage.

16.2.2 Creating the mesh

The following statements create a one-dimensional mesh which is 1 m long with a 0.1 m spacing. A contact is placed at 0 and 1 and are named contact1 and contact2 respectively.

```
from ds import *
device="MyDevice"
region="MyRegion"
```

```
###
### Create a 1D mesh
###
create_1d_mesh (mesh="mesh1")
add_1d_mesh_line (mesh="mesh1", pos=0.0, ps=0.1, tag="contact1")
add_1d_mesh_line (mesh="mesh1", pos=1.0, ps=0.1, tag="contact2")
add_1d_contact (mesh="mesh1", name="contact1", tag="contact1",
    material="metal")
add_1d_contact (mesh="mesh1", name="contact2", tag="contact2",
    material="metal")
add_1d_region (mesh="mesh1", material="Si", region=region,
    tag1="contact1", tag2="contact2")
finalize_mesh (mesh="mesh1")
create_device (mesh="mesh1", device=device)
```

16.3 Setting device parameters

In this section, we set the value of the permittivity to that of SiO 2.

```
###
### Set parameters on the region
###
set_parameter(device=device, region=region,
    name="Permittivity", value=3.9*8.85e-14)
```

16.3.1 Creating the models

Solving for the Potential, ψ , we first create the solution variable.

```
###
### Create the Potential solution variable
###
node_solution(device=device, region=region, name="Potential")
```

In order to create the edge models, we need to be able to refer to Potential on the nodes on each edge.

```
###
### Creates the Potential@n0 and Potential@n1 edge model
###
edge_from_node_model(device=device, region=region, node_model="Potential")
```

We then create the ElectricField model with knowledge of Potential on each node, as well as the EdgeInverseLength of each edge. We also manually calculate the derivative of ElectricField with Potential on each node and name them ElectricField:Potential@n0 and ElectricField:Potential@n1.

We create DField to account for the electric displacement field.

The bulk equation is now created for the structure using the models and parameters we have previously defined.

```
###
### Create the bulk equation
###
equation(device=device, region=region, name="PotentialEquation",
   variable_name="Potential", edge_model="DField",
   variable_update="default")
```

16.3.2 Contact boundary conditions

We then create the contact models and equations. We use the Python for loop construct and variable substitutions to create a unique model for each contact, contact1 bc and contact2 bc.

In this example, the contact bias is applied through parameters named contact1_bias and contact2_bias. When applying the boundary conditions through circuit nodes, models with respect to their names and their derivatives would be required.

16.3.3 Setting the boundary conditions

```
###
### Solve
###
solve(type="dc", absolute_error=1.0, relative_error=1e-10, maximum_
iterations=30)
```

16.3.4 Running the simulation

We run the simulation and see the results.

capacitance> devsim cap1d.py

DEVSIM

Version: Beta 0.01

Copyright 2009-2013 Devsim LLC

```
contact2
      (region: MyRegion)
      (contact: contact1)
      (contact: contact2)
Region "MyRegion" on device "MyDevice" has equations 0:10
Device "MyDevice" has equations 0:10
number of equations 11
Iteration: 0
     Device: "MyDevice" RelError: 1.00000e+00 AbsError: 1.00000e+00
           Region: "MyRegion" RelError: 1.00000e+00 AbsError: 1.00000e+00
                 Equation: "PotentialEquation" RelError: 1.00000e+00 AbsError:
                 1.00000e+00
Iteration: 1
      Device: "MyDevice" RelError: 2.77924e-16 AbsError: 1.12632e-16
           Region: "MyRegion" RelError: 2.77924e-16 AbsError: 1.12632e-16
                 Equation: "PotentialEquation" RelError: 2.77924e-16 AbsError:
                 1.12632e-16
contact: contact1 charge: 3.45150e-13
contact: contact2 charge: -3.45150e-13
```

Which corresponds to our expected result of 3.451510^{-13} F/cm² for a homogenous capacitor.

16.4 2D Capacitor

This example is called <code>cap2d.py</code> and is located in the <code>examples/capacitance</code> directory distributed with <code>DEVSIM</code>. This file uses the same physics as the 1d example, but with a 2d structure. The mesh is built using the <code>DEVSIM</code> internal mesher. An air region exists with two electrodes in the simulation domain.

16.5 Defining the mesh

```
from ds import *
device="MyDevice"
region="MyRegion"

xmin=-25
x1 =-24.975
x2 =-2
x3 =2
x4 =24.975
xmax=25.0
```

```
v1 = 0.1
y2 = 0.2
y3 = 0.8
v4 = 0.9
ymax=50.0
create_2d_mesh (mesh=device)
add_2d_mesh_line(mesh=device, dir="y", pos=ymin, ps=0.1)
add_2d_mesh_line(mesh=device, dir="y", pos=y1 , ps=0.1)
add_2d_mesh_line(mesh=device, dir="y", pos=y2 , ps=0.1)
add_2d_mesh_line(mesh=device, dir="y", pos=y3 , ps=0.1)
add_2d_mesh_line(mesh=device, dir="y", pos=y4 , ps=0.1)
add_2d_mesh_line(mesh=device, dir="y", pos=ymax, ps=5.0)
device=device
region="air"
add_2d_mesh_line(mesh=device, dir="x", pos=xmin, ps=5)
add_2d_mesh_line(mesh=device, dir="x", pos=x1 , ps=2)
add_2d_mesh_line(mesh=device, dir="x", pos=x2 , ps=0.05)
add 2d mesh line (mesh=device, dir="x", pos=x3 , ps=0.05)
add_2d_mesh_line(mesh=device, dir="x", pos=x4 , ps=2)
add_2d_mesh_line(mesh=device, dir="x", pos=xmax, ps=5)
add_2d_region(mesh=device, material="gas", region="air", yl=ymin, yh=ymax,...
\rightarrowxl=xmin, xh=xmax)
add_2d_region(mesh=device, material="metal", region="m1", yl=y1, yh=y2, ,_
\rightarrow x1=x1 , xh=x4)
add_2d_region(mesh=device, material="metal", region="m2", yl=y3, yh=y4, __
\rightarrowx1=x2 , xh=x3)
# must be air since contacts don't have any equations
add_2d_contact (mesh=device, name="bot", region="air", material="metal", yl=y1,
\rightarrow yh=y2, x1=x1, xh=x4)
add_2d_contact(mesh=device, name="top", region="air", material="metal", yl=y3,
\rightarrow yh=y4, x1=x2, xh=x3)
finalize_mesh (mesh=device)
create device(mesh=device, device=device)
```

16.6 Setting up the models

```
node_solution(device=device, region=region, name="Potential")
###
### Creates the Potential@n0 and Potential@n1 edge model
edge_from_node_model(device=device, region=region, node_model="Potential")
###
### Electric field on each edge, as well as its derivatives with respect to
### the potential at each node
edge model(device=device, region=region, name="ElectricField",
                 equation="(Potential@n0 - Potential@n1)*EdgeInverseLength")
edge_model(device=device, region=region, name="ElectricField:Potential@n0",
                 equation="EdgeInverseLength")
edge_model(device=device, region=region, name="ElectricField:Potential@n1",
                 equation="-EdgeInverseLength")
###
### Model the D Field
###
edge_model(device=device, region=region, name="DField",
           equation="Permittivity*ElectricField")
edge model(device=device, region=region, name="DField:Potential@n0",
           equation="diff(Permittivity*ElectricField, Potential@n0)")
edge_model(device=device, region=region, name="DField:Potential@n1",
          equation="-DField:Potential@n0")
###
### Create the bulk equation
equation(device=device, region=region, name="PotentialEquation",
 variable_name="Potential", edge_model="DField",
 variable update="default")
### Contact models and equations
###
for c in ("top", "bot"):
 contact_node_model(device=device, contact=c, name="%s_bc" % c,
           equation="Potential - %s bias" % c)
  contact_node_model(device=device, contact=c, name="%s_bc:Potential" % c,
             equation="1")
  contact_equation(device=device, contact=c, name="PotentialEquation",
             variable_name="Potential",
             node_model="%s_bc" % c, edge_charge_model="DField")
```

```
###
### Set the contact
###
set_parameter(device=device, name="top_bias", value=1.0e-0)
set_parameter(device=device, name="bot_bias", value=0.0)

edge_model(device=device, region="m1", name="ElectricField", equation="0")
edge_model(device=device, region="m2", name="ElectricField", equation="0")
node_model(device=device, region="m1", name="Potential", equation="bot_bias;")
node_model(device=device, region="m2", name="Potential", equation="top_bias;")

solve(type="dc", absolute_error=1.0, relative_error=1e-10, maximum_
iterations=30,
solver_type="direct")
```

16.7 Fields for visualization

Before writing the mesh out for visualization, the element_from_edge_model is used to calculate the electric field at each triangle center in the mesh. The components are the ElectricField_x and ElectricField_y.

16.8 Running the simulation

DEVSIM

Version: Beta 0.01

Copyright 2009-2013 Devsim LLC

```
Creating Region air
Creating Region m1
Creating Region m2
Adding 8281 nodes
Adding 23918 edges with 22990 duplicates removed
Adding 15636 triangles with 0 duplicate removed
Adding 334 nodes
Adding 665 edges with 331 duplicates removed
Adding 332 triangles with 0 duplicate removed
Adding 162 nodes
Adding 321 edges with 159 duplicates removed
Adding 160 triangles with 0 duplicate removed
Contact bot in region air with 334 nodes
Contact top in region air with 162 nodes
Region "air" on device "MyDevice" has equations 0:8280
Region "m1" on device "MyDevice" has no equations.
Region "m2" on device "MyDevice" has no equations.
Device "MyDevice" has equations 0:8280
number of equations 8281
Iteration: 0
      Device: "MyDevice" RelError: 1.00000e+00 AbsError: 1.00000e+00
           Region: "air" RelError: 1.00000e+00 AbsError: 1.00000e+00
                 Equation: "PotentialEquation" RelError: 1.00000e+00 AbsError:
                 1.00000e+00
Iteration: 1
     Device: "MyDevice" RelError: 1.25144e-12 AbsError: 1.73395e-13
           Region: "air" RelError: 1.25144e-12 AbsError: 1.73395e-13
                 Equation: "PotentialEquation" RelError: 1.25144e-12 AbsError:
                 1.73395e-13
3.35017166004e-12
-3.35017166004e-12
```

A visualization of the results is shown in Fig. 16.1.

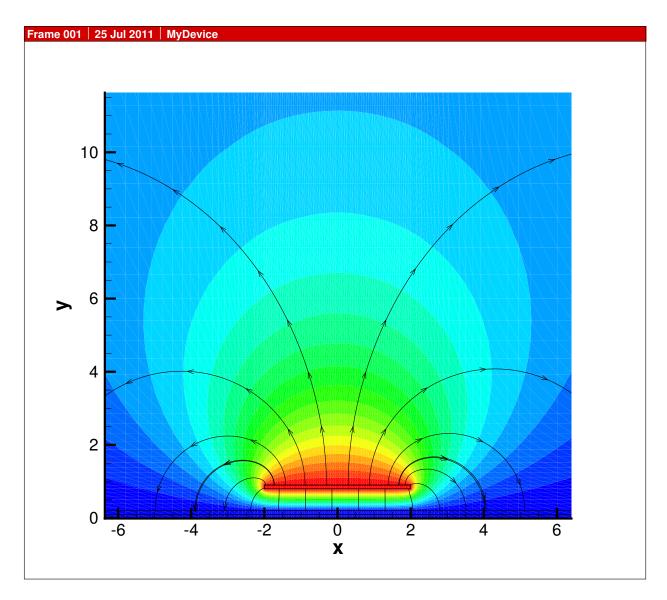


Fig. 16.1: Capacitance simulation result. The coloring is by Potential, and the stream traces are for components of ElectricField.

Chapter 17

Diode

The diode examples are located in the examples/diode. They demonstrate the use of packages located in the python_packages directory to simulate drift-diffusion using the Scharfetter-Gummel method [SG69] (page 111).

17.1 1D diode

17.1.1 Using the python packages

For these examples, python modules are provided to supply the appropriate model and parameter settings. A listing is shown in Table 17.1. The python_packages must be in your path, and may be set using the methods described in *Other packages* (page 40). The example files in the DEVSIM distribution set the path properly when loading modules.

Table 17.1: Python package files.

model_create	Creation of models and their derivatives	
ramp	Ramping bias and automatic stepping	
simple_dd	Functions for calculating bulk electron and hole current	
simple_physics	Functions for setting up device physics	

For this example, diode_1d.py, the following line is used to import the relevant physics.

```
from ds import *
from simple_physics import *
```

17.1.2 Creating the mesh

This creates a mesh 10^{-6} cm long with a junction located at the midpoint. The name of the device is MyDevice with a single region names MyRegion. The contacts on either end are called top and bot.

```
def createMesh(device, region):
    create_ld_mesh(mesh="dio")
    add_ld_mesh_line(mesh="dio", pos=0, ps=le-7, tag="top")
    add_ld_mesh_line(mesh="dio", pos=0.5e-5, ps=le-9, tag="mid")
    add_ld_mesh_line(mesh="dio", pos=le-5, ps=le-7, tag="bot")
    add_ld_contact (mesh="dio", name="top", tag="top", material="metal")
    add_ld_contact (mesh="dio", name="bot", tag="bot", material="metal")
    add_ld_region (mesh="dio", material="Si", region=region, tag1="top", tag2="bot")
    finalize_mesh(mesh="dio")
    create_device(mesh="dio", device=device)

device="MyDevice"
    region="MyRegion"

createMesh(device, region)
```

17.2 Physical Models and Parameters

```
####
#### Set parameters for 300 K
SetSiliconParameters(device, region, 300)
set_parameter(device=device, region=region, name="taun", value=1e-8)
set_parameter(device=device, region=region, name="taup", value=1e-8)
####
#### NetDoping
CreateNodeModel(device, region, "Acceptors", "1.0e18*step(0.5e-5-x)")
CreateNodeModel(device, region, "Donors",
                                            "1.0e18*step(x-0.5e-5)")
CreateNodeModel(device, region, "NetDoping", "Donors-Acceptors")
print_node_values(device=device, region=region, name="NetDoping")
####
#### Create Potential, Potential@n0, Potential@n1
CreateSolution(device, region, "Potential")
#### Create potential only physical models
CreateSiliconPotentialOnly(device, region)
####
#### Set up the contacts applying a bias
for i in get_contact_list(device=device):
 set parameter(device=device, name=GetContactBiasName(i), value=0.0)
 CreateSiliconPotentialOnlyContact(device, region, i)
```

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```
####
#### Initial DC solution
solve(type="dc", absolute_error=1.0, relative_error=1e-12, maximum_
⇒iterations=30)
####
#### drift diffusion solution variables
CreateSolution(device, region, "Electrons")
CreateSolution(device, region, "Holes")
####
#### create initial guess from dc only solution
####
set_node_values(device=device, region=region,
name="Electrons", init_from="IntrinsicElectrons")
set_node_values(device=device, region=region,
 name="Holes", init from="IntrinsicHoles")
###
### Set up equations
CreateSiliconDriftDiffusion(device, region)
for i in get contact list(device=device):
 CreateSiliconDriftDiffusionAtContact(device, region, i)
###
### Drift diffusion simulation at equilibrium
solve(type="dc", absolute_error=1e10, relative_error=1e-10, maximum_
→iterations=30)
####
#### Ramp the bias to 0.5 Volts
####
v = 0.0
while v < 0.51:
 set_parameter(device=device, name=GetContactBiasName("top"), value=v)
 solve(type="dc", absolute_error=1e10, relative_error=1e-10, maximum_
→iterations=30)
 PrintCurrents(device, "top")
 PrintCurrents(device, "bot")
 v += 0.1
####
#### Write out the result
write_devices(file="diode_1d.dat", type="tecplot")
```

17.2.1 Plotting the result

A plot showing the doping profile and carrier densities are shown in Fig. 17.1. The potential and electric field distribution is shown in Fig. 17.2. The current distributions are shown in Fig. 17.3.

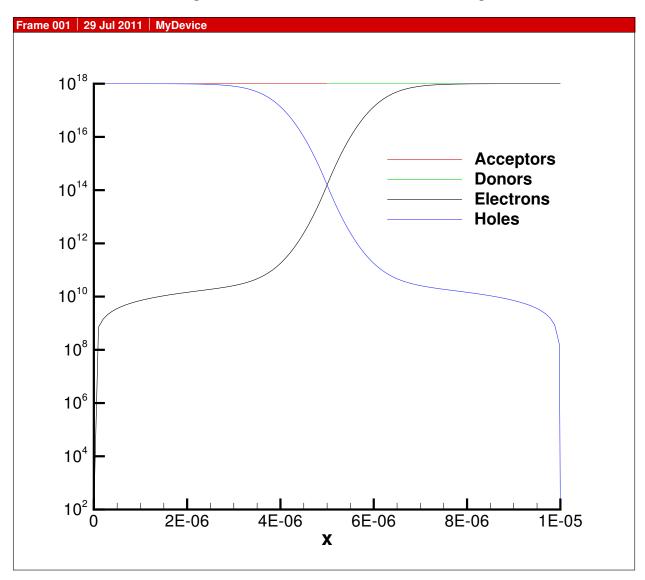


Fig. 17.1: Carrier density versus position in 1D diode.

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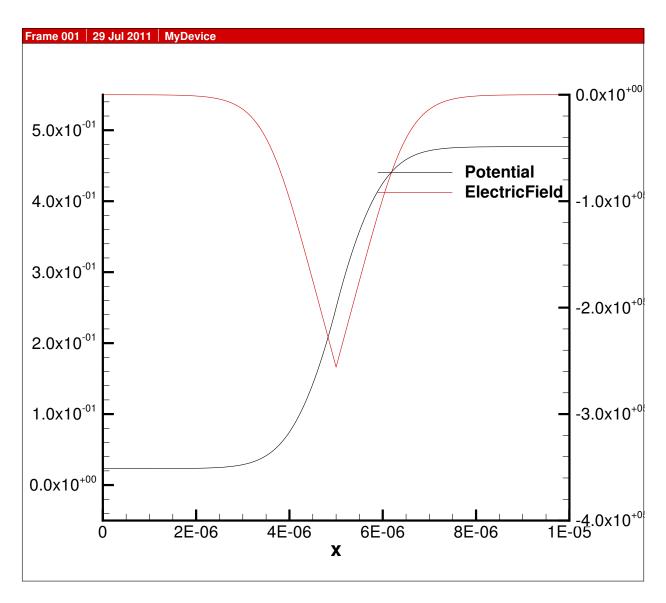


Fig. 17.2: Potential and electric field versus position in 1D diode.

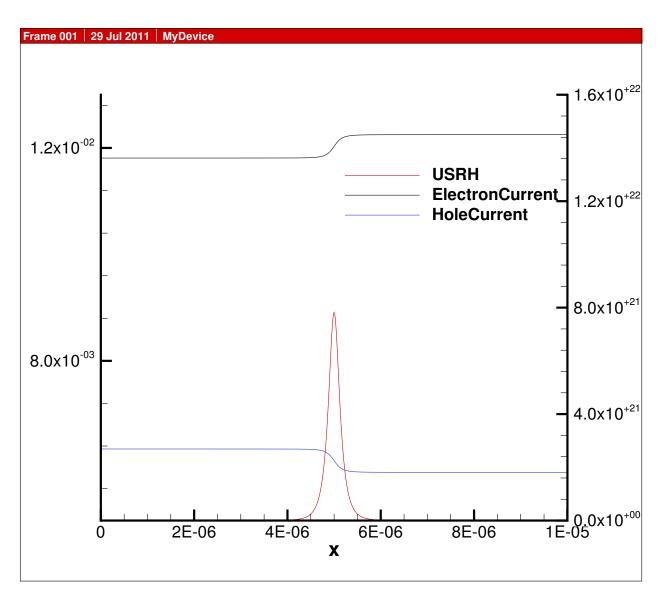


Fig. 17.3: Electron and hole current and recombination.

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